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RAYTHEON CO QUINCY MASS INDUSTRIAL COMPONENTS OPERATION F/G 9/5
MANUFACTURING METHODS AND TECHNOLOGY ENGINEERING (MM AND TE) PR--ETC(U)
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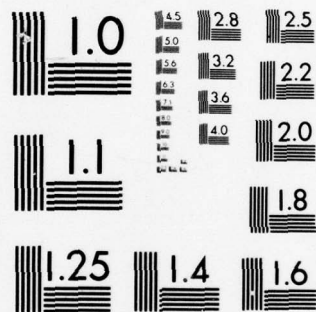
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FOR FURTHER TRAN

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MANUFACTURING METHODS AND
TECHNOLOGY ENGINEERING (MM&TE) PROGRAM
FOR THE ESTABLISHMENT OF PRODUCTION TECHNIQUES
FOR HIGH DENSITY THICK FILM CIRCUITS
USED IN CRYSTAL OSCILLATORS

FOURTH QUARTERLY PROGRESS REPORT
29 MAY 1977 - 27 AUGUST 1977

CONTRACT NO. DAAB07-76-C-8119

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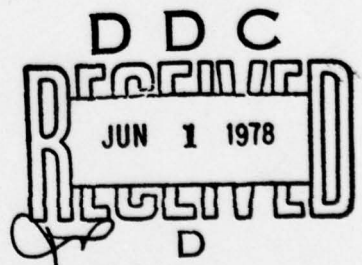
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PREPARED BY

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MANUFACTURING METHODS AND
TECHNOLOGY ENGINEERING (MM&TE) PROGRAM FOR THE ESTABLISHMENT
OF PRODUCTION TECHNIQUES FOR HIGH DENSITY THICK FILM CIRCUITS
USED IN CRYSTAL OSCILLATORS

FOURTH QUARTERLY PROGRESS REPORT
29 MAY 1977 - 27 AUGUST 1977

CONTRACT NO. DAAB07-76-C-8119

PRESENTED BY

C. G. ALEX

PREPARED BY


CHARLES T. MARTIN
RICHARD COLSON
CHARLES MORRIS

OBJECT OF STUDY

The objectives of the program are to establish production techniques for high density thick film hybrid microcircuits used in crystal oscillators and to produce quantities of a 20 MHz temperature - compensated, voltage - controlled crystal oscillator (TCVCXO) using these techniques.

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ABSTRACT

Production techniques are being established for a thick film hybrid microelectronic 17-22 MHz, temperature-compensated, voltage-controlled crystal oscillator. In the engineering phase of the program, the redesign of the VCXO and TCFG substrates to relieve corral dimension and circuit density problems has been completed. The first lot of engineering samples has progressed through the pre-aging electrical testing, and five units were undergoing aging at the close of the period. These units are non-conforming, having been assembled prior to the redesign effort. The second lot of engineering samples, using the redesigned substrates, is in process.

TABLE OF CONTENTS

<u>SECTION</u>		<u>PAGE</u>
1.0	INTRODUCTION	1
2.0	PROCESS DEVELOPMENT	3
	2.1 Parallel-Seam Soldering and Welding	3
	2.2 Test Procedures	3
3.0	FIXTURING AND TOOLING	4
	3.1 Trimming Holding Fixture	4
	3.2 Compatible Substrate Tooling for Laser Trimmer and Screening Equipment	4
	3.3 Testing Fixturing	4
4.0	SUBSTRATE ASSEMBLY (10-lot samples)	5
	4.1 Substrate Redesign	5
	4.2 Trimming Efforts	6
5.0	MODULE ASSEMBLY AND TESTING (10-lot samples)	8
	5.1 Pre-Aging Electrical Testing	8
	5.2 Description of Test Setups	9
	5.3 Discussion of Tests	14
	5.4 Aging	18
6.0	PROGRESS ON 15-LOT SAMPLES	19
	6.1 Parts and Materials Procurement	19
	6.2 Fabrication of Substrates	19
7.0	CONCLUSIONS	20
8.0	PROGRAM FOR NEXT QUARTER	21

TABLE OF CONTENTS (cont)

APPENDICES

- A. Identification of Personnel
- B. Pre-Aging Electrical Test Data
- I. TRS31388 TCVCXO Module Functional Test
- J. TRS31389 TCVCXO Module Transient Frequency
Stability Test
- K. TRS31390 TCVCXO Module Temperature Test

LIST OF ILLUSTRATIONS

<u>Figure</u>		<u>Page</u>
4-1	Substrate Component Assembly VCXO Hybrid Regulator Version	7
5-1	Schematic Diagram of Functional Test Box	10
5-1	Transient Stability Test Setup - Alternate Method	13

LIST OF TABLES

<u>Table</u>		<u>Page</u>
5-1	Pre-Aging Functional Test - Data Summary	11
5-2	Transient Frequency Stability - Data Summary	17

1.0 INTRODUCTION

The engineering phase of this manufacturing methods and technology program consists of the following tasks:

1. Electrical breadboard construction
2. Breadboard evaluation
3. Module configuration design
4. Process flow plan generation
5. Hybrid microcircuit parts selection
6. Hybrid microcircuit parts and bonding tools procurement
7. Thick film processing materials procurement
8. Potting shells and encapsulant materials procurement
9. Hybrid microcircuit layout design
10. Layout artwork generation
11. Thick film printing screen procurement
12. Assembly drawing generation
13. Assembly materials procurement
14. Assembly process development
15. Encapsulation process development
16. Hermetic sealing process development
17. Hermetic sealing parts and materials procurement
18. Test flow plan generation
19. Test procedure generation
20. Test fixture design and fabrication
21. Thick film substrate fabrication
22. Substrate assembly (10-lot)
23. Electrical testing of substrate assemblies (pre-seal tests)
(10-lot)
24. Hermetic sealing of substrate assemblies (10-lot)
25. Leaking testing of hermetically sealed substrate assemblies
(10-lot)

26. Module assembly (10-lot)
27. Electrical testing of assembled modules (pre-aging) (10-lot)
28. Module aging (10-lot)
29. Electrical testing of modules (final tests) (10-lot)
30. Substrate assembly (15-lot)
31. Electrical testing of substrate assemblies (pre-seal tests) (15-lot)
32. Hermetic sealing of substrate assemblies (15-lot)
33. Leak testing of sealed substrate assemblies (15-lot)
34. Module assembly (15-lot)
35. Electrical testing of assembled modules (pre-pot tests) (15-lot)
36. Module encapsulation (15-lot, as required)
37. Electrical testing of encapsulated modules (post-pot tests) (15-lot, as required).
38. Module aging (15-lot)
39. Electrical testing of modules (final tests) (15-lot)

The 10-lot and 15-lot designations refer to the two lots of deliverable engineering samples required by the contract. At the close of the 4th quarter, the following items were considered to be completed: 1-3, 5, 7-14, 18, 20, 22-27. Work is continuing on items 4, 6, 15-17, 19, 21, 28, 30.

Like previous reports, this report is divided into four major categories for purposes of discussion: Process Development, Fixturing and Tooling, Substrate Assembly, and Module Assembly and Testing.

2.0 PROCESS DEVELOPMENT

2.1 Parallel-Seam Soldering and Welding

Seam-soldering experiments were conducted during the third quarter using gold-tin solder preforms. Visual examination of the soldered parts showed inconsistent flow and wetting of the solder. Gross leaks were revealed at the poorly wetted areas. It was suspected that the parts had not been properly cleaned.

Because of the unsuccessful experiments with parallel-seam soldering, both TCFG and VCXO substrate assemblies were oven sealed for use in fabricating the 10-lot modules by a parallel-seam welding process. Further experiments with parallel-seam soldering were not conducted during this report period.

Leak testing of the sealed substrates revealed fine leaks in some of the welds. It is presumed that these leaks were caused by non-optimized welding currents and pressures. For example, too low a welding current would cause leaks, while too high a welding current would heat and fracture the corral glass, thus causing leaks at that interface. The sealing process investigation is continuing, and the process will be refined for use on future lots.

2.2 Test Procedures

Test procedures for use during module production have been completed. These are:

TCFG Functional	TCVCXO Temperature Stability
VCXO Functional	TCFG Functional Trim
TCVCXO Functional	VCXO Functional Trim
TCVCXO Transient Frequency Stability	

3.0 FIXTURING AND TOOLING

3.1 Trimming Holding Fixture

In attempting to trim VCXO substrate assemblies to a given oscillator frequency, spurious oscillations made frequency measurements difficult. Since these oscillations had not occurred during functional testing, it was assumed to be a laser fixturing problem. Therefore, the trimming holding fixture was modified to incorporate the use of an edge connector during functional trimming of VCXO substrate assemblies. This was necessary since the occurrence of spurious oscillations with the initial set-up indicated the need for contact between the crystal and the VCXO assembly more intimate than probes could provide. The fixture will be further modified to incorporate a thermocouple to aid in TCFG functional trimming.

The modified fixture was used to finish the VCXO substrate trims with no further oscillation problems. However, difficulties were encountered in trimming for the 2000 Hz frequency shift because of the limited trim ranges of the resistors involved. This problem has been corrected by the VCXO substrate redesign.

3.2 Compatible Substrate Tooling for Laser Trimmer and Screening Equipment

To provide accurate registration between the thick-film screener and laser trimmer, similar sets of substrate mounting fixtures are being fabricated for each piece of equipment. The substrate edge will touch at one point in the short dimension and at two points in the long dimension.

3.3 Test Fixturing

The test fixture designed and fabricated for module temperature testing completed the test fixturing effort on the engineering phase of the TCVCXO program.

4.0 SUBSTRATE ASSEMBLY (10-lot samples)

4.1 Substrate Redesign

Problems were encountered during the third quarter in the assembly and passive trim of the TCFG and VCXO substrates for the 10-lot construction effort. The major difficulty resulted from the fact that the glass fillets of the corrals extended toward the substrate interior more than had been anticipated. In some places, the fillets partially covered resistors and made trimming difficult. In the assembly operation, the corral dimensions and the circuit density prevented the use of conventional die-bonding and beam-lead-bonding tools.

Several alternative solutions were considered. One possible solution to the trimming problem, passive trimming before corral attachment, was rejected because the greater than 500°C heat required in the corral attach process could seriously affect resistor values.

Changes in the corral shape were investigated but were abandoned because of structural weakness, assembly complexity (involving added cost and/or extended time of operation), or potential hermetic sealing problems.

Eventually, it was determined that the best solution would be a redesign of both substrates. However, implementation of this redesign required several changes in the design ground rules.

- a. Both TCFG and VCXO substrate assemblies were changed from three to four resistor paste blends to achieve better control of resistor as-fired values.
- b. The use of beam-lead devices was abandoned in favor of chip-and-wire devices because of the non-availability of the former and to increase reliability.

The TCFG substrate assembly redesign was accomplished without a great deal of difficulty. The layout was shown in Figure 5-1 of the third quarterly report.

For the VCXO hybrid assembly, a more drastic change in concept was required to make the circuit manufacturable. Because there was no room on the substrates to move various devices away from the corral wall, it was decided eventually to move part of the circuitry into the large vacant space which had been reserved for the flatpack crystal mounting pad, since the HC-18 crystal then being used pending the availability of the ceramic flatpack, was mounted outside the substrate. A logical candidate for use of the area was the 9-volt regulator circuit, which has been so designed that it can be removed at a later date and placed into a separate external package when the flatpack crystals become available. The redesigned VCXO layout is shown in Figure 4-1. It can be compared with the original layout shown in Figure 2-4 of the second quarterly report.

All necessary art work for both TCFG and VCXO substrate layout redesigns has been generated and new printing screens reflecting the 10-lot sample submission were completed.

4.2 Trimming Efforts

The VCXO substrate was passively trimmed on the abrasive trimmer. Initial efforts indicated that this is an appropriate technique. However, some difficulties arose in determining resistor loops and subsequent probe placement.

The TCFG active trim procedure has been reviewed. The main areas of concern are the placement of the probe for monitoring substrate temperature and selection of an appropriate AC ratio meter for gain adjustments. It is thought that temperature probe placement can be accomplished by taping to the substrate near the edge connector pins.

Trim probe cards for both TCFG and VCXO are being defined and ordered.

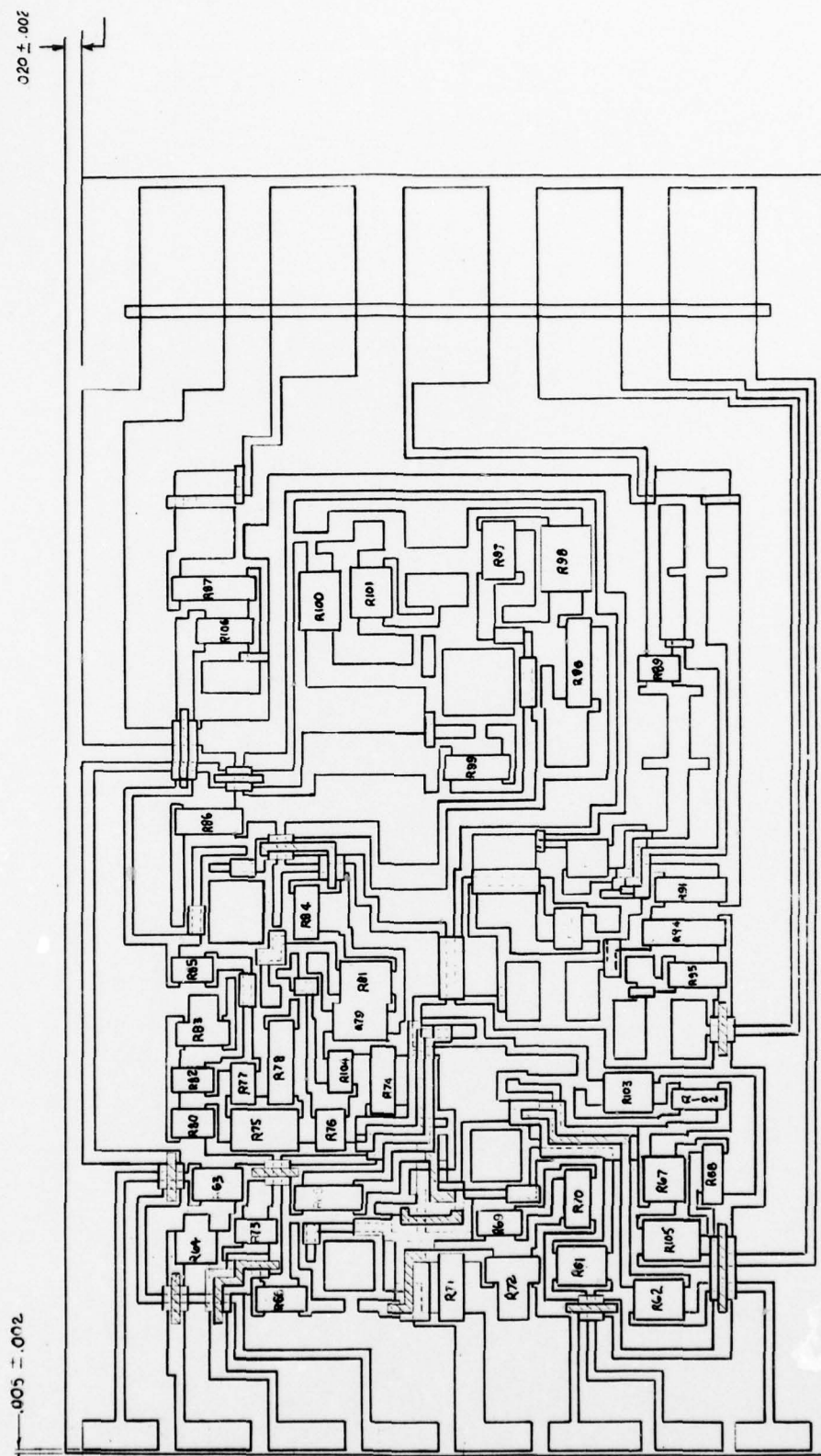


Figure 4-1. Substrate Component Assembly VCXO Hybrid Regulator Version

5.0 MODULE ASSEMBLY AND TESTING (10-lot samples)

The first engineering samples of the TCVCXO modules were assembled for the 10-lot submission. Although no problems were encountered, soldering the ribbon jumpers in place took longer than anticipated. However, because of yield loss in resistor trimming and VCXO substrate assembly, there was only enough material to assemble 8 TCVCXO modules. The 2-unit deficit in the 10-lot delivery will not be made up since both substrate assemblies have been redesigned. The present 10-lot modules are nonrepresentative of future builds.

5.1 Pre-Aging Electrical Testing (10-lot samples)

The pre-aging electrical testing of the TCVCXO modules was carried out in 3 phases in compliance with the referenced Test Requirements Specification (TRS):

1. Functional Test (TRS 31388)
2. Transient Frequency Stability Test (TRS 31389)
3. Temperature Test (TRS 31390)

Copies of the specifications are included in the Appendix.

Although the problems involved in functional trimming prevented meeting specifications entirely, 7 of 8 units subjected to functional test were considered working, and data were recorded. The eighth sample would not oscillate after assembly and is being fault isolated.

The remaining 7 units were temperature tested over a range of -40° to $+75^{\circ}\text{C}$. During these tests, the modules' center frequencies and upper and lower deviations were plotted. Two modules failed this test, both showing large frequency shifts with temperature. The remaining 5 units looked good except in the -30° to -40°C range, where the frequency tailed off on all 5 units.

Transient frequency stability testing showed all 5 modules to be stable within 1 Hz over the 5 to 100 ms test range.

Copies of the test data sheets for the 8 modules subjected to pre-aging electrical testing are included in the Appendix.

5.2 Description of Test Setups

5.2.1 Functional Tests

The functional tests were accomplished by means of the test setup shown in Figure 1 of TRS 31388. The circuitry within the Functional Test Box, as shown in Figure 5-1, consists of the components necessary to switch the input voltages and output loading as required to perform the tests listed in Table 5-1.

The input supply voltage is derived from Zener diodes and may be switched between +10, +12, and +15 volts for the frequency/voltage sensitivity test. The voltage may be applied through a series transistor switch, normally shorted, which is used to interrupt periodically the supply voltage for the transient stability test. The input current is measured by clipping a DC current probe on a current loop which is in series with the transistor switch.

A 5-volt zener diode provides a level for the digital and control inputs, which may be switched separately between ground and 5 volts. The analog voltage input is derived from a low impedance resistor network fed by an external +2.4-volt source. The various voltage levels are selected from taps by means of a switching arrangement which also permits a symmetric reversal of levels. An AC signal may also be switched in, either directly or through a 200K ohm resistor, for the analog input impedance measurement. The output loading may be varied between 1200, 1000, and 800 ohms by switching.

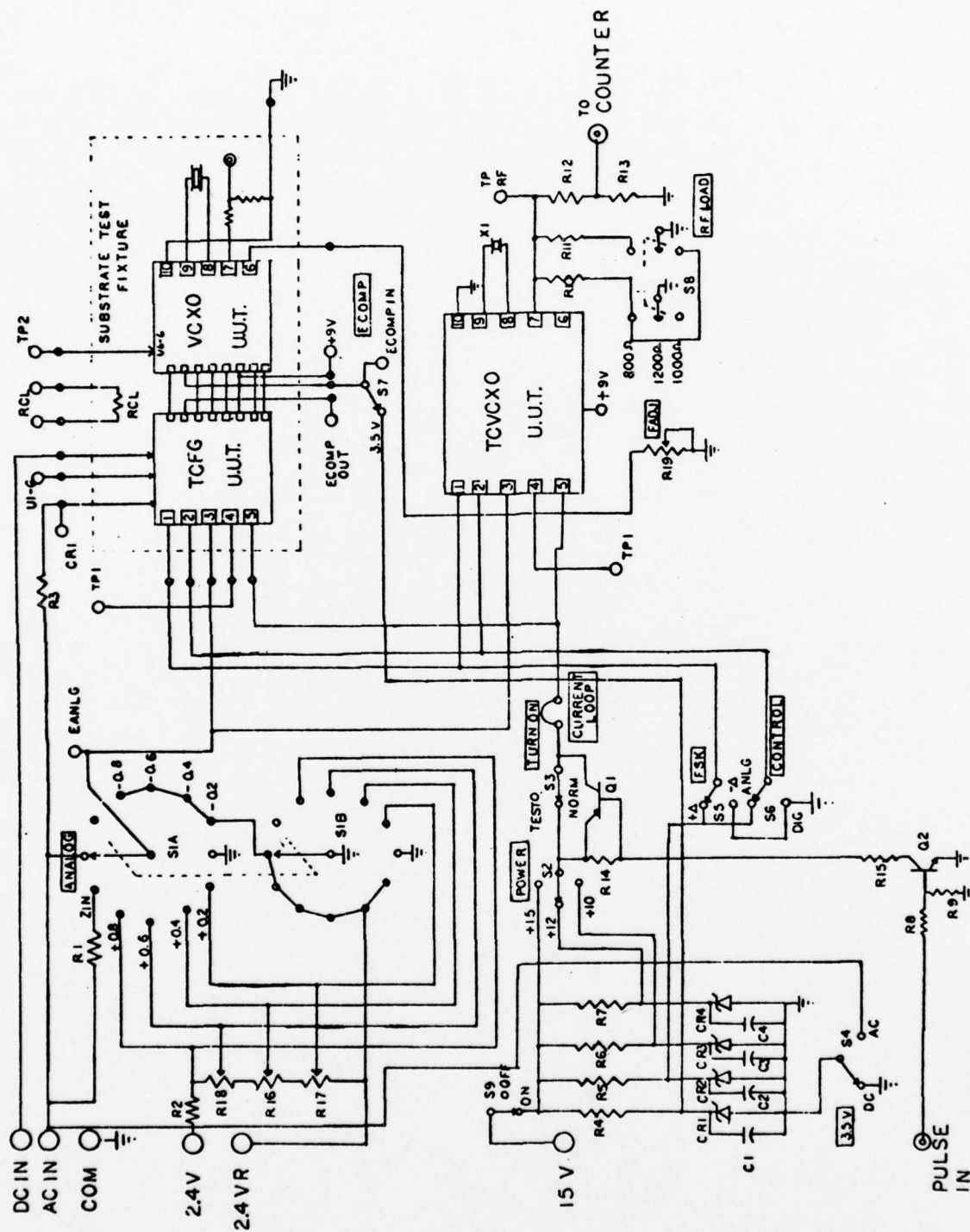


Figure 5-1. Schematic Diagram of Functional Test Box

Table 5-1 Pre-Aging Functional Tests - Data Summary

Test	Unit	Spec Limit	Module Serial No.							
			1	2	3	4	5	7	8	
Input Power	ma	4.16 (max)	3.45	3.55	3.40	3.45	3.20	3.50	3.45	
Output Voltage	V _{pp}	1.50 (min)	1.10	1.12	1.00	1.20	1.12	1.20	1.20	
Frequency vs 12V	±ppm	0.25 (max)	0.19	0.00	0.11	0.11	0.06	0.06	0.00	
Frequency vs Load	±ppm	0.25 (max)	0.19	0.11	0.11	0.11	0.11	0.11	0.11	
Analog Zin	KΩ	200KΩ (min)	196	184	194	186	191	189	187	
Analog Deviation Sensitivity	Hz/V	500	466	471	574	453	454	460	452	
Analog Deviation Linerarity	± %	5(max)	2.4	1.6	2.5	1.9	1.4	1.2	1.4	
FSK Deviation	±Hz	300(min) 325(max)								
FSK Deviation Total	Hz	600(min) 650(max)	427	573	712	547	504	558	549	
Frequency Adjustment	±ppm	5(min)	52	53	53	48	54	57	54	

5.2.2 Transient Stability Tests

The test setup used for the transient stability test is shown in Figure 5-2. It is an alternate setup to that shown in Figure 1 of TRS 31389 and uses the HP 5306A computing frequency counter in a slightly different manner. In this setup, the pulse generator applies 12 volts to the unit under test through the series transistor switch in the Functional Test Box, and simultaneously triggers the delay circuit in the oscilloscope. The delayed sweep from the scope is then used to furnish a counting interval to the HP 5360A counter. The duration of the delayed sweep is 10 ms to provide a resolution of 1 Hz, and the position of the sweep is controlled by the scope delay setting. Thus, the counting interval is visible as a brightened segment of the oscillator output trace. The counting interval is positioned from 5 to 15 ms and 90 to 100 ms in accordance with specification requirements, but it can also be varied continuously along the outer trace to verify that the frequency is stable throughout.

5.2.3 Temperature Testing

The test setup shown in Figure 1 of TRS 31390, with one change, was used to generate the temperature characteristics as required by the product specification. Because a D/A converter was not available, the RF output was beat against a stable source in a mixer, and the difference frequency was fed to an F/V converter. The output of the F/V converter was then used to drive the Y channel of the XY plotter.

The electronic switch, designed for this setup, is used to switch the analog input between zero volts and symmetric positive and negative levels, while coordinating the lifting and dropping of the pen to prevent smearing. A more complete description of this unit was given in the Third Quarterly Progress Report.

The oven temperature is varied at a constant rate by means of a motor-driven potentiometer. The temperature is sensed with an RCL

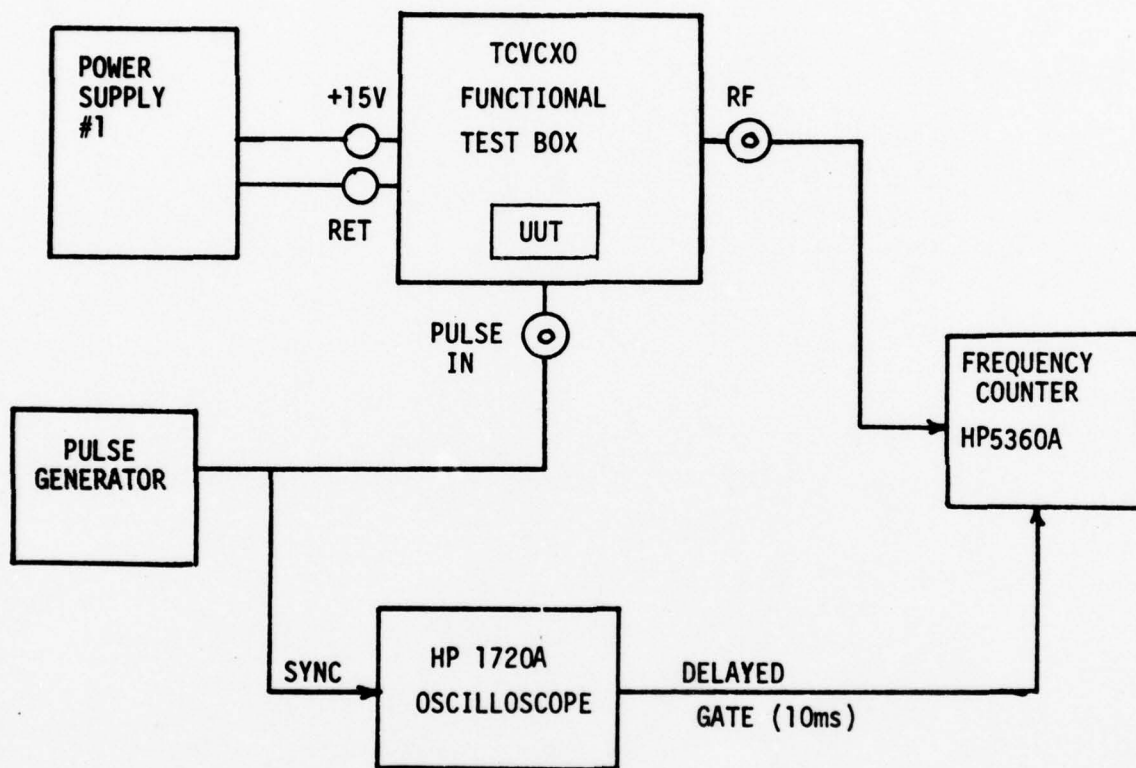


Figure 5-2. Transient Stability Test Setup
Alternate Method

temperature-sensitive wire-wound resistor with a constant positive temperature coefficient. The RCL sensor is used in a bridge to provide a DC voltage output which is proportional to temperature, this voltage then being used to drive the X channel of the plotter.

The setup is limited to testing one unit at a time.

5.3 Discussion of Tests

5.3.1 Functional Tests

The data recorded for the pre-aging functional tests are summarized in Table 5-1, with specification limits included for reference.

- a. Input Power (SCS-483, para. 3.2.3). The measurement was made with the supply voltage at the nominal value of +12.0 volts. This corresponds to an average power of about 42 mw, which is comfortably below specification maximum of 50 mw. At the maximum value of 15 volts, however, the average power would be just out of specification at about 52 mw. It is recommended that the specification be clarified with respect to the supply voltage.
- b. Output Voltage (SCS-483, para. 3.2.4). The RF voltages ranged from 1.1 to 1.2 volts peak-to-peak, which is below the required minimum of 1.5 Vpp listed on the data sheets. The limit is actually specified as 0.5 volts rms in SCS-483, which is equivalent to 1.41 Vpp for a sinusoid. Measurement accuracy could be improved by using an RV voltmeter rather than an oscilloscope, although unusual waveforms, if any, would not be so detected. Possibly a specification for output distortion should be considered in view of the nonlinear waveform. Such a measurement might also be desirable

for high volume testing where individual waveforms would not normally be visually observed.

- c. Frequency-Voltage Stability (SCS-483, para. 3.11). The frequency-voltage stability is specified as ± 0.25 ppm, for a supply voltage variation of +3 volt and -2 volt about a nominal of +12 volt. Performance data indicate that this requirement is readily met.
- d. Frequency-Load Stability (SCS-483, para. 3.12). As with the frequency-voltage stability, the limit is ± 0.25 ppm for a load variation of 1000 ohm ± 200 ohm. The data sheets show a typical frequency change of ± 0.11 ppm which is well within specification limits.
- e. Analog Input Impedance (SCS-483, para. 3.19). The analog input impedance is determined essentially by comparing the unknown Z_{in} with a resistor in the functional test box which is known to be 200K within 0.1 %. The value of Z_{in} is computed from the formula:
- $$Z_{in} = \frac{200K \Omega}{\frac{V_{cal}}{V_z} - 1}$$
- Where V_{cal} and V_z are the voltages measured at terminals AC_{in} and E_{anlg} of Figure 5.1, respectively.
- f. Analog Deviation Sensitivity (SCS-483, para. 3.20). Table 5-1 shows all modules but one were lower than the specified 500 Hz/V. Allowable limits for this parameter will need to be specified.
- g. Analog Deviation Linerity (SCS-483, para. 3.21). Table 5-1 shows that all modules were well within the specified 5%.

- h. FSK Deviation (SCS-483, para. 3.20). The FSK deviation is tabulated in two ways in Table 5-1, as a positive and negative deviation from center frequency and as a total digital deviation. Since no center frequency was recorded for the pre-aging tests only total deviation is provided.
- i. Frequency Adjustment Range (SCS-483, para. 3.17). The specification requires a minimum of ± 5 ppm of nominal frequency for a 25K potentiometer. Table 5-1 shows adjustment ranges relative to the center of the tuning range. Data indicate that there is more than sufficient adjustment range to accommodate crystal manufacturing tolerance and aging.

5.3.2 Transient Frequency Stability Tests (SCS-483, para. 3.13)

Table 5-2 summarizes the transient frequency stability test data. Difficulties were encountered in making this measurement because of the tendency of the modules to oscillate in a spurious mode. These spurious oscillations, of variable duration, occurred at approximately 5 to 7 MHz, depending on the loading and on the individual modules. It was found that by using the 50 ohm input to the HP5360A computing counter, but with the coaxial cable shield not connected at the counter end, the spurious oscillations would stop in most cases before 10 ms. The circuit would then oscillate in the normal mode, controlled by the crystal, and the transient stability measurement could be made.

Table 5-2. Transient Frequency Stability-Data Summary

<u>TCVCXO S/N No.</u>	<u>Pre-Aging Test Δf (Hz)</u>
1	Note 1
2	0
3	Note 2
4	+1
5	0 (Note 3)
7	Note 4
8	+1

- Notes:
1. Spurious oscillation at 5 MHz prevented measurement of transient stability.
 2. Spurious oscillation.
 3. Spurious oscillations lasted approximately 3 to 8 ms. Initial frequency measurement made from 10 to 20 ms.
 4. Spurious oscillation at 7 MHz prevented measurement of transient stability.

Where data could be taken, it was found that the variation from 10 to 100 ms was 1 Hz at most. A 10 ms counting period was required by the HP5360A to achieve a resolution of 1 Hz, so the frequency was actually measured during the interval from 5 to 15 ms and again from 90 to 100 ms. The former was then subtracted from the latter to give the Δf recorded in Table 5.2. The results are seen to be well within the specification limit of 10 Hz.

5.3.3 Temperature Tests (SCS-483, para. 3.10).

Reference to the individual temperature plots in the Appendix shows that only one of the units, S/N 7, is entirely within the limits of ± 2 ppm over the range from -40° to $+75^{\circ}\text{C}$. The general cubic shape of the crystal is still discernible in the module curves, which suggests that there is insufficient gain for the temperature compensation voltage channel. Also, the generally large negative slope below -20°C suggests that either the "thermometer" or the diode function generator is inadequate in this region.

5.4 Aging (SCS-483, para. 3.14)

Of the seven TCVCXO modules which underwent final pre-aging electrical tests, five units were submitted for aging. Two units, S/N 1 and S/N 3 were not put into aging because of their inadequate temperature compensation circuits. The aging process will continue into the next quarterly report period, and the results will be reported in Quarterly Progress Report No. 5.

6.0 PROGRESS ON 15-LOT SAMPLES

6.1 Parts and Materials Procurement

Chip-and-wire components were ordered for the 15-lot modules to replace the beam-lead devices used in the 10-lot modules.

6.2 Fabrication of Substrates

The redesigned VCXO substrates which utilize the internal crystal pad location for the 9-volt regulator were fabricated for the 15-lot modules. The TCFG screens, previously redesigned, were used to fabricate the TCFG sections for the 15-lot effort.

7.0 CONCLUSIONS

The major accomplishments during the fourth quarter of this program have been the completion of test procedures for use during module production, completion of the first engineering samples of the TCVXO modules for the 10-lot submission, completion of pre-aging electrical testing of the 10-lot engineering samples, and initiation of aging for modules passing the pre-aging tests. Based on experience with the 10-lot modules, redesign of both TCFG and VCXO substrates has been completed. Effort is continuing on the various trimming problems encountered in this program, including modification of the laser trimming holding fixture to overcome the spurious oscillation problem, and on the hermetic sealing problem.

8.0 PROGRAM FOR NEXT QUARTER

During the next quarter, aging of the 10-lot TCVCXO engineering modules will be completed, and these modules will be subjected to the required post-aging functional testing. TCFG and VCXO screening, passive trim and assembly will be completed for the 15-lot engineering samples. Documentation transfer and generation of source control documentation will be continued, as will the hermetic sealing study and experimentation.

APPENDIX A

IDENTIFICATION OF PERSONNEL

IDENTIFICATION OF PERSONNEL

The following Raytheon Equipment Development Laboratories professional personnel performed work on this program during the fourth quarter. The man- hours of work charged to the program by each individual is reported, as is the program contributions and technical background of each.

Charles T. Martin*
(40 hours)

TCVCXO Engineering Phase
Project Manager; also prepared
engineering phase monthly technical
reports and third quarterly report.

Leland Woodworth*
(14 hours)

Prepared TCVCXO engineering phase
monthly cost reports and supervised
production control activity for TCVCXO
parts and materials procurement.

Stanley Czerepak*
(51 hours)

Accomplished layout redesign and
artwork generation for TCFG and
VCXO hybrid microcircuits.

Richard Bemis*
(140 hours)

Performed testing of TCFG and VCXO
hybrids and testing and aging of 10-lot
modules.

Charles Morris*
(314 hours)

Provided engineering assistance to
production facility during 15-lot
manufacturing start-up; participated in
preparation of engineering phase monthly
technical report and third quarterly
report; designed resistor trim probe
cards for redesigned hybrids; assisted in
testing of TCFG and VCXO hybrids and
TCVCXO modules.

Thomas Salzer**
(33 hours)

Performed hermetic sealing of hybrid
microcircuits for 10-lot modules.

Frank Cheriff***
(4 hours)

Supervised assembly of 10-lot modules.

* See first quarterly report for individual's technical background.

** See second quarterly report for individual's technical background.

*** See third quarterly report for individual's technical background.

The above listed personnel were assisted by the following support functions at the level of effort indicated.

Q.C. Engineering	2 hours.
Q.C. Inspection	13 hours.
Production Control	26 hours.
Manufacturing (10-lot)	125 hours.
Drafting (artwork generation)	37 hours.
Environmental Testing	7 hours.
Supervision Administration	51 hours.
Miscellaneous	2 hours.

Total level of effort for this quarter was 1063 hours.

Major effort on the TCVCXO program was transferred during this quarter to the Raytheon Industrial Components Operation plant at Quincy, Massachusetts. The following ICO personnel participated in the program to the extent indicated:

Christos Alex
(38 hours)

TCVCXO Program Manager. General supervision of the Quincy effort. B.S. Chemical Engineering. Senior Program Manager, Microelectronics, responsible for all production programs.

Kenneth Pilczak
(55 hours)

TCVCXO Project Engineer, provided technical lead for program. Contributed to the production engineering effort. B.S.E.E.

John J. Queenan
(12 hours)

Conducted resistor paste experiments and supervised laboratory effort in screening and assembly of first engineering samples. Engineering Specialist, supervises microelectronics laboratory.

John Senoski
(88 hours)

Responsible for transfer of design to manufacturing, including documentation.

The above listed personnel were assisted by the following support functions at the level of effort indicated:

Engineering Laboratory Support	41 hours.
Drafting	144 hours.

Total level of effort for this quarter:

Equipment Development Laboratories	1063 hours.
Industrial Components Operation	376 hours.

APPENDIX B

PRE-AGING ELECTRICAL TEST DATA

1.	TCVCXO Functional Tests	B- 1
2.	Transient Frequency Stability	B- 8
3.	Analog Deviation	B-14
4.	Temperature Characteristics	B-21

RAYTHEON

RAYTHEON COMPANY
LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31388

SHEET

REV -

TCVCXO FUNCTIONAL TESTS

TCVCXO MODULE NO. 1

TCFG NO. 10

VCXO NO. 3

FREQ. 21 MHz

XTAL NO. 51

TEST Pre-Aging

V @ 9V REG

V @ TP.1

DATE: 6-28-77

BY: R.I. Bemis

TEST NO.	SUPPLY	INPUTS	ECNT	CONDITION	SPEC.	TEST POINT	ACTUAL VALUE	COMMENT
		EANL	EDIC					
1. (Input P. r)	12	0	0	5	-	4.16 MA Max.	Cur. Lp. 3.45	
2. (RF OUT.)	12	0	0	5	R _L : 1000Ω	1.5 VPP ^{Min} Max	Rf Tp 1.10	
3. (FR.-V.-Stab.)	10 12 15	0	0	5	R _L : 1000Ω	±0.25 PPM ±5.3 Hz	Rf Tp 20 999 200 201 197	-1.0 Hz -4.0
4. (Fr.-Ld.-Stab.)	12	0	0	5	800 1000 1200	±0.25 PPM ±5.3 Hz	Rf Tp 20 999 199 200 196	-1.0 Hz -4.0
5. (Analog Z-in)	12	0	0	5	1.00VRMS 0.01, 1 kHz	200 K	TP1 Cal: 1.037 Zin: 0.513 196 K _Ω	
6. (Analog Freq.-Dev. & Dev. Lin.)	12	0.75 0.6 0.4 0.2 0.0 0.2 0.4 0.6	0	5	At E ang 0 v Adjust Fadj for Center Frequency After Stabilization (Mid Adj. Range)	356.3 to 393.7	Rf 20 998 839 8 930 9 017 106 188 370 368 479 575	-349 -258 -171 -82 0 +12 +180 +291 +387
f Adj. Range: 21 000 240 20 998 124 ± 1083		0.75 0.79				-393.7 to -356.3		Average Sensitivity: 466 Hz/v
7. (Fsk. Dev.)	12	0	0	0	with Cntl in Anlg and Eanl OV, adjust Fadj for center freq after 'Stab.	300 to 325 -325 to -300	Rf 20 999 478 20 998 905	Total Deviation 573

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SHEET

REV

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TCVCXO FUNCTIONAL TESTS

TCVCXO MODULE NO. 2
TCFG NO. 8
VCXO NO. 21

FREQ. 18 MHz
XTAL NO. 23

TEST Pre-Aging
V @ 9V REG
V @ TP1

DATE: 6-24-77

BY: R. I. Bernis

TEST NO.	SUPPLY	INPUTS	ECNT	CONDITION	SPEC.	TEST POINT	ACTUAL VALUE	COMMENT
		EANL	EDIC					
1. (Input P/c)	12	0	0	5	-	4.16 MA Max.	Cur. Lp. 3.55	
2. (RF OUT.)	12	0	0	5	R _L : 1000 Ω	1.5 VPP ^{Min} Max Rf Tp	1.12	
3. (FR.-V.-Stab.)	10 12 15	0	0	5	R _L : 1000 Ω	± 0.25 PPM ± 4.5 Hz	18000 012 012 012	+0.0 Hz -0.0
4. (Fr.-Ld.-Stab.)	12	0	0	5	800 1000 1200	± 0.25 PPM ± 4.5 Hz	18000 014 012 011	+2.0 Hz -1.0
5. (Analog Z-in)	12	0	0	5	1.00VRMS 0.01, 1 kHz	200 K Ω TP1	Cal: 1.011 .485 Zin: 184 K Ω	
6. (Analog Freq.-Dev. & Dev. Lin.)	12	0.75 0.6 0.4 0.2 0.0 0.2 0.4 0.6	0	5	At E _{ang} 0 v Adjust Fadj for Center Frequency After Stabilization (Mid Adj. Range)	356.3 to 393.7 -393.7 to -356.3	17999 375 467 558 645 727 817 919 024 119	-352 -260 -169 -82 0 +90 +192 +297 +392 Average Sensitivity: 471 Hz/v
7. (Fsk. Dev.)	12	0	0	0	with Cntl in Anlg and Eanl OV, adjust Fadj for center freq after stab.	300 to 325 -325 to -300	18000 027 17999 454	Total Deviation: 573 Hz

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CODE IDENT NO.

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SPEC NO.

31388

SILEY

REV

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TCVCXO FUNCTIONAL TESTS

TCVCXO MODULE NO. 3
TCFG NO. 12
VCXO NO. 14

FREQ. 18 MHz
XTAL NO. 22

TEST Pre-Aging

V @ 9V REG

V @ TP.1

DATE: 6-27-77

BY: R.I. Bemis

TEST NO.	INPUTS			ECNT	CONDITION	SPEC.	TEST POINT	ACTUAL VALUE	COMMENT
	SUPPLY	EANL	EDIC						
1. (Input P _r)	12	0	0	5	-	4.16 MA Max.	Cur. Lp.	3.40	
2. (RF OUT.)	12	0	0	5	R _L : 1000Ω	1.5 VPP Max	Mix Rf Tp	1.0	
3. (FR.-V.- Stab.)	10	0	0	5	R _L : 1000Ω	± 0.25 PPM ± 4.5 Hz	Rf Tp	17999510	+ 0.0 Hz
	12							510	
	15							508	- 2.0
4. (Fr.-Ld.- Stab.)	12	0	0	5	800	± 0.25 PPM ± 4.5 Hz	Rf Tp	17999510	+ 1.0 Hz
					1000			509	
					1200			507	- 2.0
5. (Analog Z-in)	12	0	0	5	1.00VRMS 0.01, 1 kHz	200 K	TP1	Cal: 1.035 Zin: .509 194 KΩ	
6. (Analog Freq.- Dev. & Dev. Lin.) Adj. Range: 18000457 19998560 1897 ± 948	12	0.75	.79	5	At Eang	356.3 to 393.7	RF	17998997	- 512
		0.6			0 v			9133	- 376
		0.4			Adjust			268	- 241
		0.2	.0		Fadj for			392	- 117
		0.0			Center			509	0
		0.2			Frequency			617	+ 108
		0.4			After			719	+ 210
		0.6			Stabilize			815	+ 306
		0.75	.79		tion	-393.7 to -356.3		904	+ 395
					(Mid Adj. Range)				Average Sensitivity: 574 Hz/v
7. (Fsk. Dev.)	12	0	5	0	with Cntl in Anlg and Eanl OV, adjust Fadj for center freq after 'Stab.	300 to 325	RF	1	Total Deviation:
								17999830	
			0			-325 to -300		17999118	712 Hz

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CODE IDENT NO.
49956

SPEC NO. 31388
SHEET REV -

TCVCXO FUNCTIONAL TESTS

TCVCXO MODULE NO. 4 FREQ. 18 MHz TEST Pre-Aging
TCFG NO. 3 XTAL NO. 29 V @ 9V REG 9.003
VCXO NO. 27 V @ TP.1 _____
DATE: 6-28-77 BY: R.I. Bemis

TEST NO.	INPUTS				CONDITION	SPEC.	TEST POINT	ACTUAL VALUE	COMMENT
	SUPPLY	EANL	EDIG	ECNT					
1. (Input P'c)	12	0	0	5	-	4.16 MA Max.	Cur. LP.	3.45	
2. (RF OUT.)	12	0	0	5	R _L : 1000Ω	1.5 VPP Max	RF Tp	1.20	
3. (FR.-V.- Stab.)	10	0	0	5	R _L : 1000Ω	± 0.25 PPM ± 4.5 Hz	RF Tp	17 999 409	0 Hz - 2
	12							409	
	15							407	
4. (Fr.-Ld.- Stab.)	12	0	0	5	800 1000 1200	± 0.25 PPM ± 4.5 Hz	RF Tp	17 999 411	+ 2 Hz - 1
								409	
								408	
5. (Analog Z-in)	12	0	0	5	1.00VRMS 0.01, 1 kHz	200 K	TP1	Cal: 1.036 Zin: 0.499 186 ka	
6. (Analog Freq.- Dev. & Dev. Lin.) Adj. Range: 18 000 265 17 998 555 1 710 ± 855	12	0.75	0.79	5	At E _{ang}	356.3 to 393.7	RF	17 999 031	- 379
		0.6			0 v			130	- 280
		0.4			Adjust			229	- 181
		0.2	0		Fadj for			322	- 88
		0.0			Center			410	0
		0.2			Frequency			493	+ 83
		0.4			After			572	+ 162
		0.6			Stabilize			656	+ 246
		0.75	0.79		tion	-393.7 to -356.3		747	+ 337
					(Mid Adj.) Range				Average Sensitivity: 453 Hz/v
7. (Fsk. Dev.)	12	0	5	0	with Cntl in Anlg and Eanl OV, adjust Fadj for center freq	300 to 325	RF	17 999 669	Total Deviation: 547 Hz
			0		-325 to -300			17 999 122	

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CODE IDENT NO.

49956

SPEC NO.

31388

SHEET

REV -

TCVCXO FUNCTIONAL TESTS

TCVCXO MODULE NO. 5
TCFG NO. 4
VCXO NO. 10

FREQ. 18 MHz

TEST Pre-Aging

XTAL NO. 2

V @ 9V REG

V @ TP 1

DATE: 6/28/77

BY: R.I. Bemis

TEST NO.	SUPPLY	INPUTS	ECNT	CONDITION	SPEC.	TEST POINT	ACTUAL VALUE	COMMENT
		EANL	EDIO					
1. (Input P ₁)	12	0	0	5	-	4.16 MA Max.	Cur. Lp. 3.20	
2. (RF OUT.)	12	0	0	5	R _L = 1000Ω	1.5 VPP Max Min	Rf Tp 1.12	
3. (FR.-V.- Stab.)	10 12 15	0	0	5	R _L = 1000Ω	± 0.25 PPM ± 4.5 Hz	Rf Tp 17 999 604 604 603	0 Hz -1
4. (Fr.-Ld.- Stab.)	12	0	0	5	800 1000 1200	± 0.25 PPM ± 4.5 Hz	Rf Tp 17 999 605 604 602	+1 Hz -2 Hz
5. (Analog Z-in)	12	0	0	5	1.00VRMS 0.01, 1 kHz	200 K	TP1 Cal: 1.035 Zin: .505 191 KΩ	
6. (Analog Freq.- Dev. & Dev. Lin.) f Adj. Range: 18000678 17 998 735 1943 ± 974	12	0.75 0.6 0.4 0.2 0.0 0.2 0.4 0.6 0.75	.79 0	5	At E _{ang} 0 v Adjust Fadj for Center Frequency After Stabiliza- tion (Mid Adj. Range)	356.3 to 393.7 -393.7 to -356.3	Rf 17 999 214 316 417 513 603 688 769 848 932	-389 -287 -186 -90 0 +85 +166 +245 +329 Average Sensitivity: 454 Hz/v
7. (Fsk. Dev.)	12	0	0	5 0	with Cntl in Anlg and Eanl OV, adjust Fadj for center freq after 'stab.	300 to 325 -325 to -300	Rf 17 999 859 17 999 305	Total Deviation: 504 Hz

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SPEC NO.

31388

SHEET

REV -

TCVCXO FUNCTIONAL TESTS

TCVCXO MODULE NO. 7

TCFG NO. 6

VCXO NO. 9

FREQ. 18 MHz

XTAL NO. 20

TEST Pre-Aging

V @ 9V REG

V @ TP.1

DATE: 6-28-77

BY: R.I. Bemis

TEST NO.	INPUTS				CONDITION	SPEC.	TEST POINT	ACTUAL VALUE	COMMENT
	SUPPLY	EANL	EDIC	LCNT					
1. (Input P. c)	12	0	0	5	-	4.16 MA Max.	Cur. Lp.	3.50	
2. (RF OUT.)	12	0	0	5	$R_L = 1000 \Omega$	1.5 VPP ^{Min} Max	Rf Tp	1.20	
3. (FR.-V.-Stab.)	10	0	0	5	$R_L = 1000 \Omega$	± 0.25 PPM ± 4.5 Hz	Rf	17999635	0 Hz
	12						Tp	635	
	15							634	-1 Hz
4. (Fr.-Ld.-Stab.)	12	0	0	5	$\frac{800}{1000}$ $\frac{1000}{1200}$	± 0.25 PPM ± 4.5 Hz	Rf	17999637	+2 Hz
							Tp	635	
								633	-2 Hz
5. (Analog Z-in)	12	0	0	5	1.00VRMS 0.01, 1 kHz	200 K	TP1	Cal: 1.036 Zin: .503 189 K Ω	
6. (Analog Freq.-Dev. & ev. Lin.) + Adj. Range: 18000 656 17998 615 2041 ± 1022	12	0.75	0.79	5	At E _{ang} 0 v Adjust Fadj for Center Frequency After Stabilization (Mid Adj. Range)	356.3 to 393.7	Rf	17999281	-354
		0.6						373	-262
		0.4						465	-170
		0.2	0					552	-83
		0.0						635	0
		0.2						716	+81
		0.4						812	+177
		0.6						914	+279
		0.75	0.79					1008	+373
									Average Sensitivity: 460 Hz/v
7. (Fsk. Dev.)	12	0	5	0	with Cntl in Anlg and Eanl OV, adjust Fadj for center freq after 'Stab.	300 to 325 -325 to -300	Rf	17999928	Total Deviation:
			0					17999370	558 Hz

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CODE IDENT NO.

49956

SPEC NO.

31388

SHEET

REV -

TCVCXO FUNCTIONAL TESTS

TCVCXO MODULE NO. 8

TCFG NO. 7

VCXO NO. 23

FREQ. 18 MHz

XTAL NO. 24

TEST Pre-Aging

V @ 9V REG

V @ TP.1

DATE: 6-28-77

BY: R.I. Bemis

TEST NO.	INPUTS				CONDITION	SPEC.	TEST POINT	ACTUAL VALUE	COMMENT
	SUPPLY	EANL	EDIC	ECNT					
1. (Input P.c)	12	0	0	5	-	4.16 MA Max.	Cur. Lp.	3.45	
2. (RF OUT.)	12	0	0	5	$R_L = 1000\Omega$	1.5 VPP Min Max	Rf Tp	1.20	
3. (FR.-V.- Stab.)	10	0	0	5	$R_L = 1000\Omega$	± 0.25 PPM ± 4.5 Hz	Rf Tp	17 999 604	0 Hz 0
	12							604	
	15							604	
4. (Fr.-Ld.- Stab.)	12	0	0	5	800	± 0.25 PPM ± 4.5 Hz	Rf Tp	17 999 606	+ 2 Hz - 1 Hz
					1000			604	
					1200			603	
5. (Analog Z-in)	12	0	0	5	1.00VRMS 0.01, 1 kHz	200 K	TP1	Cal: 1.036 Zin: 1.500 187k Ω	
6. (Analog Freq.- Dev. & Dev. Lin.) Adj. Range: 18000 578 17 999 630 1948 ± 974	12	0.75	0.79	5	At E _{ang}	356.3 to 393.7	Rf	17 999 253	- 352
		0.6			0 v			345	- 260
		0.4			Adjust			436	- 169
		0.2	0		Fadj for			523	- 82
		0.0			Center			605	0
		0.2			Frequency			685	+ 80
		0.4			After			776	+ 171
		0.6			Stabiliza-			875	+ 270
		0.75	0.79		tion	-393.7 to -356.3		967	+ 362
					(Mid Adj. Range)				Average Sensitivity: 452 Hz/v
7. (Fsk. Dev.)	12	0	5	0	with Cntl in Anlg and Eanl OV, adjust Fadj for center freq	300 to 325	Rf	17 999 877	Total Deviation:
			0		after 'Stab.	-325 to -300		17 999 328	549 Hz

TCVCXO MODULES, 10 LOT

S/N /

TRANSIENT FREQUENCY STABILITY (INITIAL TURN ON)

(Pgh. 3.13, SCS-483)

	<u>PRE-AGING</u>	<u>POST-AGING</u>
f_0 (Initial Steady State)	<u> </u>	<u> </u>
f_1 (Avg., 5 to 15 ms)	<u> </u>	<u> </u>
f_2 (Avg., 90 to 100 ms)	<u> </u>	<u> </u>
Δf ($f_2 - f_1$)	<u> </u>	<u> </u>
f_3 (Final Steady State)	<u> </u>	<u> </u>

REMARKS:

*Oscillates in spurious mode at approx.
5 MHz.*

TCVCXO MODULES, 10 LOT

S/N 2

TRANSIENT FREQUENCY STABILITY (INITIAL TURN ON)

(Pgh. 3.13, SCS-483)

	<u>PRE-AGING</u>	<u>POST-AGING</u>
f_0 (Initial Steady State)	<u>17,999,555</u>	
f_1 (Avg., 5 to 15 ms)	<u>- - 554</u>	
f_2 (Avg., 90 to 100 ms)	<u>- - 554</u>	
Δf ($f_2 - f_1$)	<u>0</u>	
f_3 (Final Steady State)	<u>- - 556</u>	

REMARKS:

TCVCXO MODULES, 10 LOT

S/N

4

TRANSIENT FREQUENCY STABILITY (INITIAL TURN ON)

(Pgh. 3.13, SCS-483)

	<u>PRE-AGING</u>	<u>POST-AGING</u>
f_0 (Initial Steady State)	<u>18,000,000</u>	
f_1 (Avg., 5 to 15 ms)	<u>300</u>	
f_2 (Avg., 90 to 100 ms)	<u>301</u>	
Δf ($f_2 - f_1$)	<u>+1</u>	
f_3 (Final Steady State)	<u>303</u>	

REMARKS:

TCVCXO MODULES, 10 LOT

S/N

5

TRANSIENT FREQUENCY STABILITY (INITIAL TURN ON)

(Pgh. 3.13, SCS-483)

	<u>PRE-AGING</u>	<u>POST-AGING</u>
f_0 (Initial Steady State)	<u>18,000,573</u>	
f_1 (Avg., 5 to 15 ms)	<u>- - 572</u>	
f_2 (Avg., 90 to 100 ms)	<u>- - 572</u>	
Δf ($f_2 - f_1$)	<u>0</u>	
f_3 (Final Steady State)	<u>- - 572</u>	

REMARKS:

Does not turn on reliably in 5 ms. f_1 measured from 10 to 20 ms.

TCVCXO MODULES, 10 LOT

S/N 7

TRANSIENT FREQUENCY STABILITY (INITIAL TURN ON)

(Pgh. 3.13, SCS-483)

	<u>PRE-AGING</u>	<u>POST-AGING</u>
f_0 (Initial Steady State)	<u>17,199.377</u>	
f_1 (Avg., 5 to 15 ms)	<u> </u>	
f_2 (Avg., 90 to 100 ms)	<u> </u>	
Δf ($f_2 - f_1$)	<u> </u>	
f_3 (Final Steady State)	<u> </u>	

REMARKS:

Spurious mode of oscillation @ approx. 7 MHz
prevented measurement of transient stability.

TCVCXO MODULES, 10 LOT

S/N

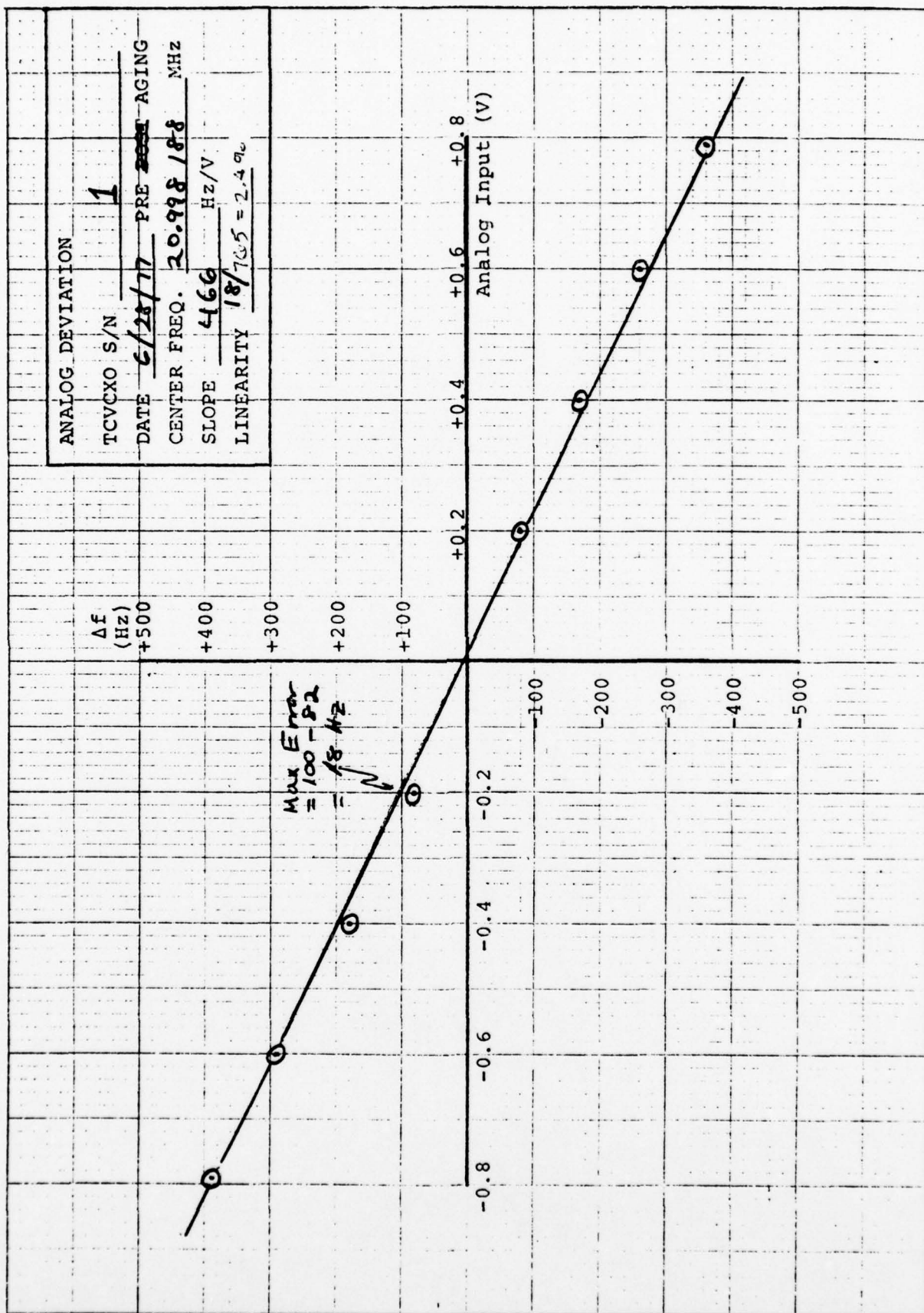
8

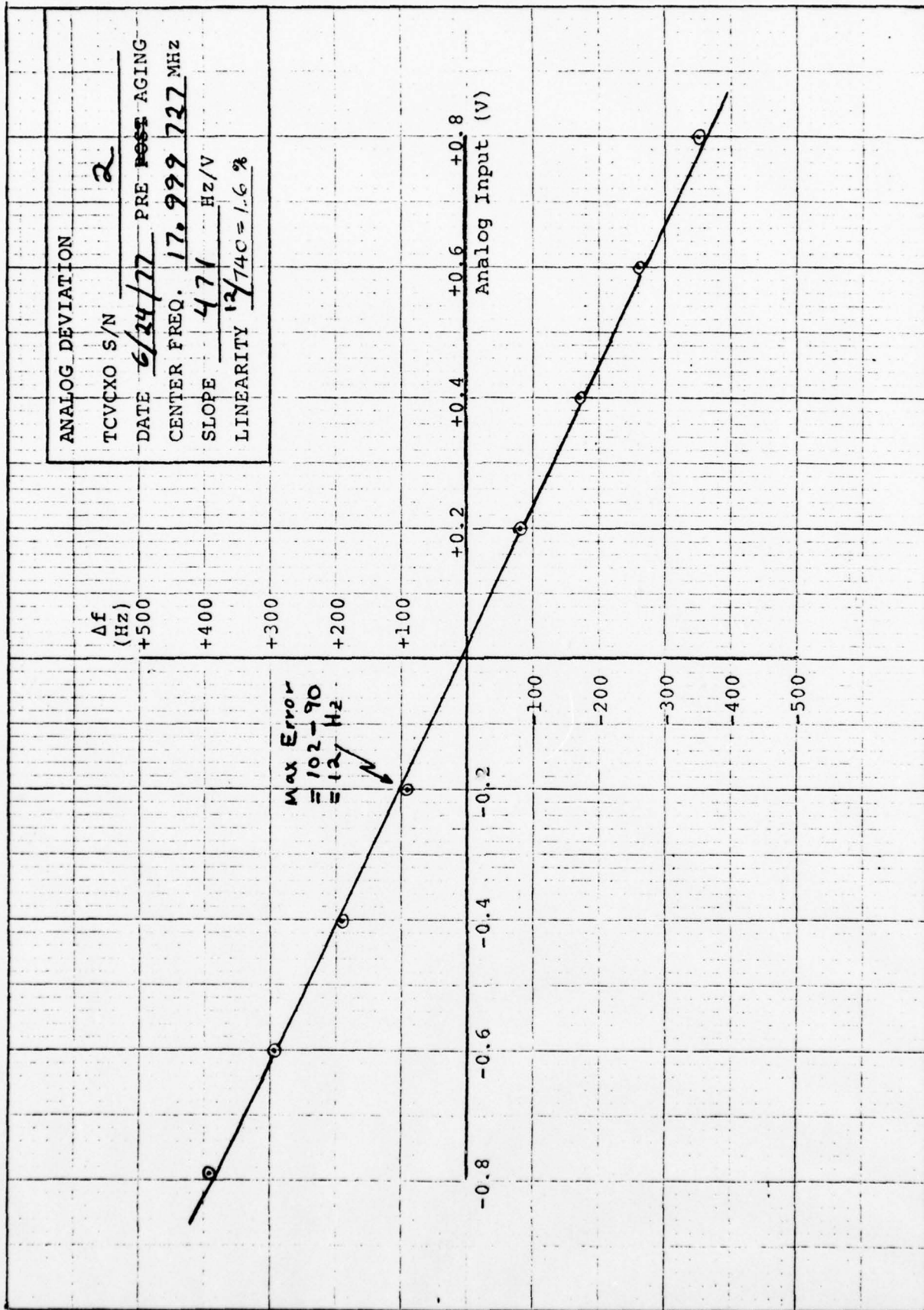
TRANSIENT FREQUENCY STABILITY (INITIAL TURN ON)

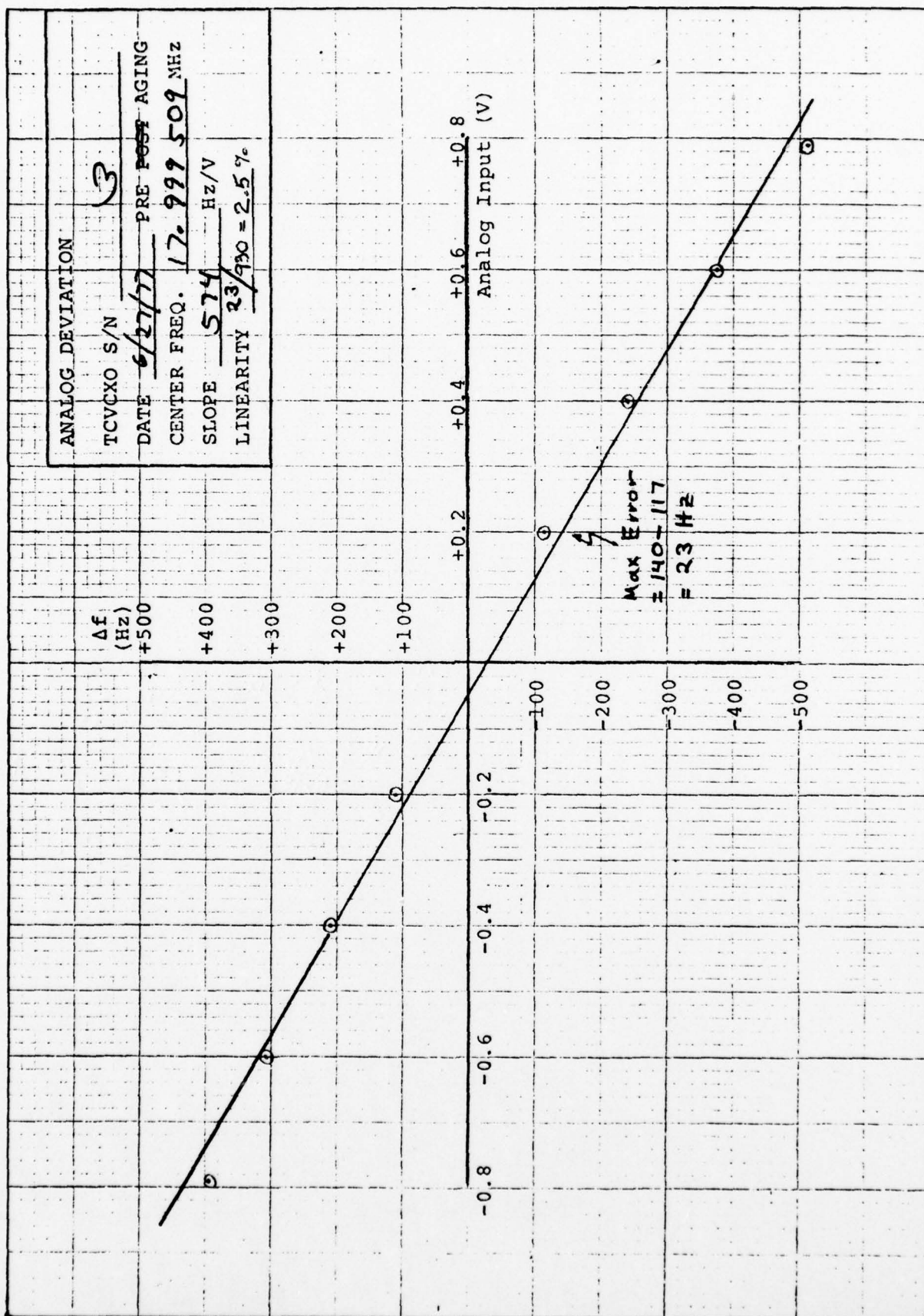
(Pgh. 3.13, SCS-483)

	<u>PRE-AGING</u>	<u>POST-AGING</u>
f_0 (Initial Steady State)	<u>17,799,341</u>	
f_1 (Avg., 5 to 15 ms)	<u>347</u>	
f_2 (Avg., 90 to 100 ms)	<u>348</u>	
Δf ($f_2 - f_1$)	<u>+1</u>	
f_3 (Final Steady State)	<u>348</u>	

REMARKS:

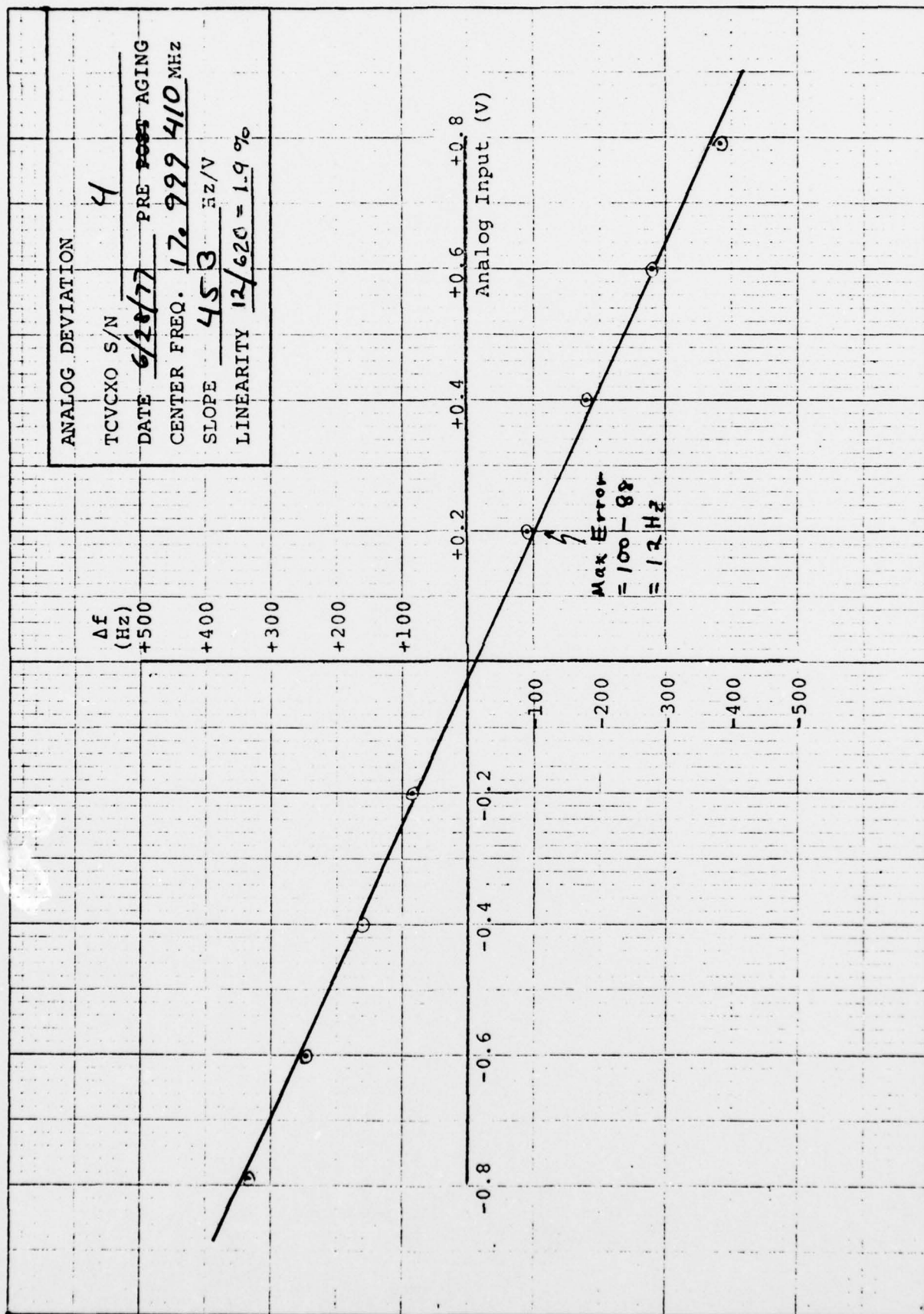


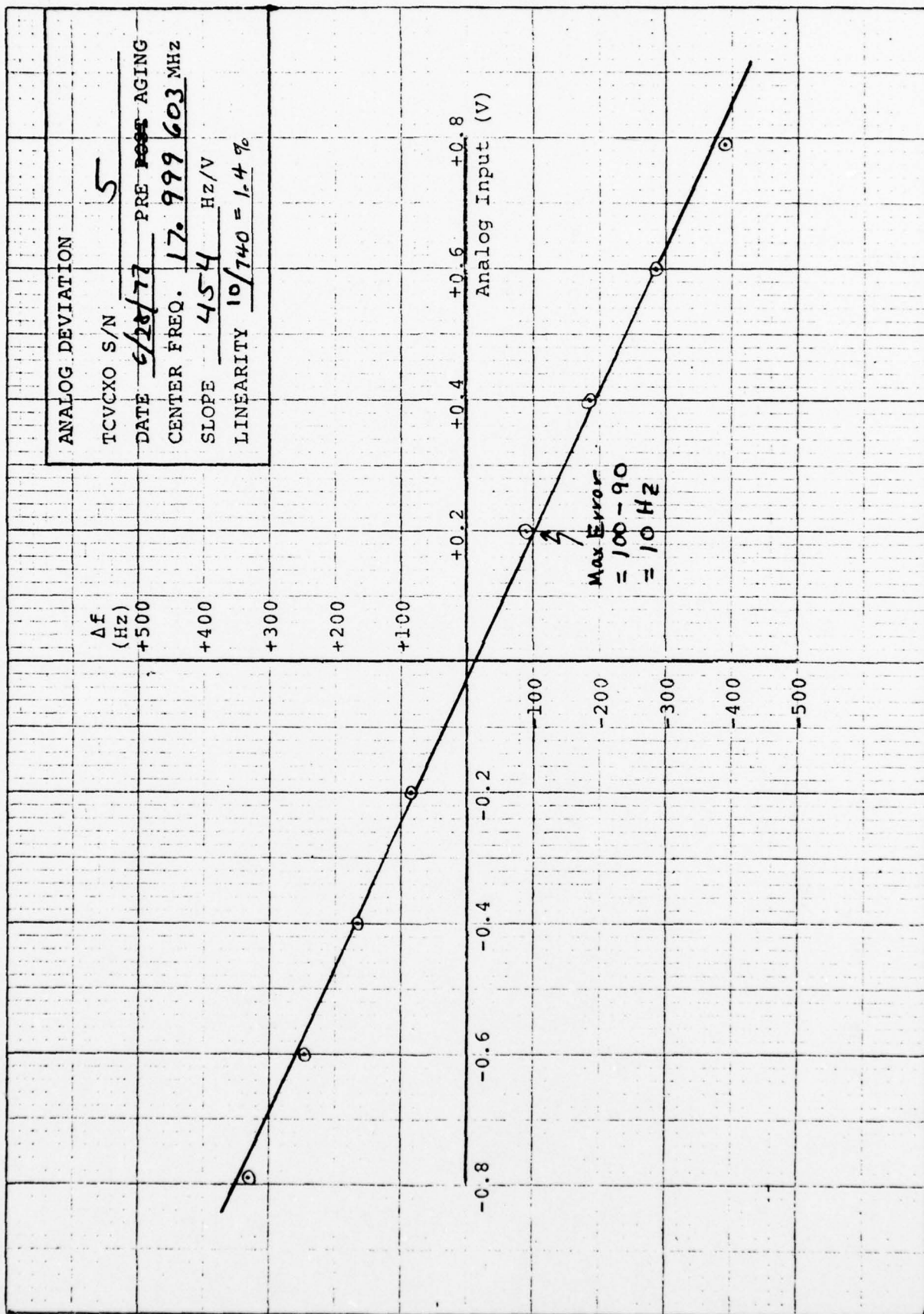


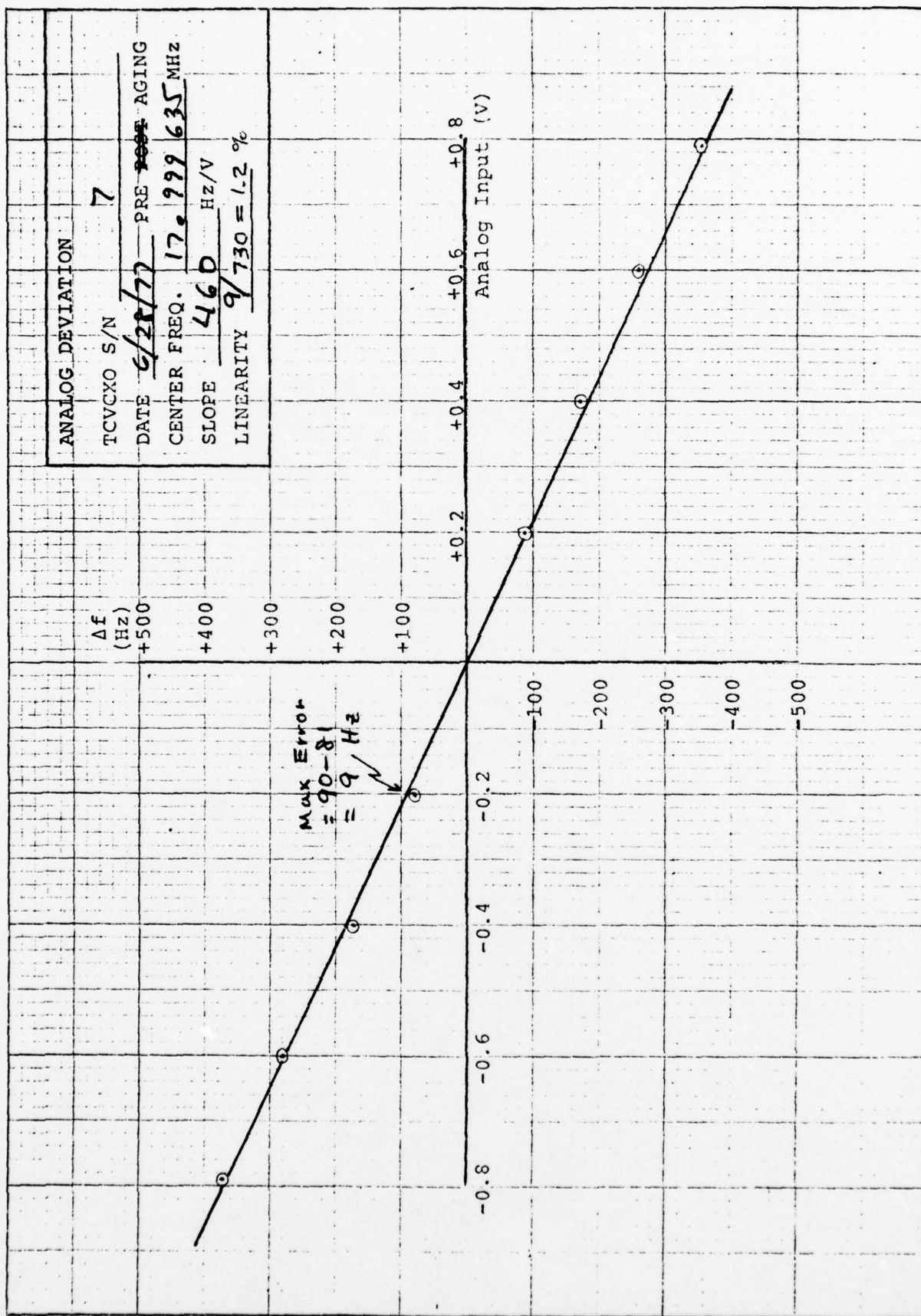


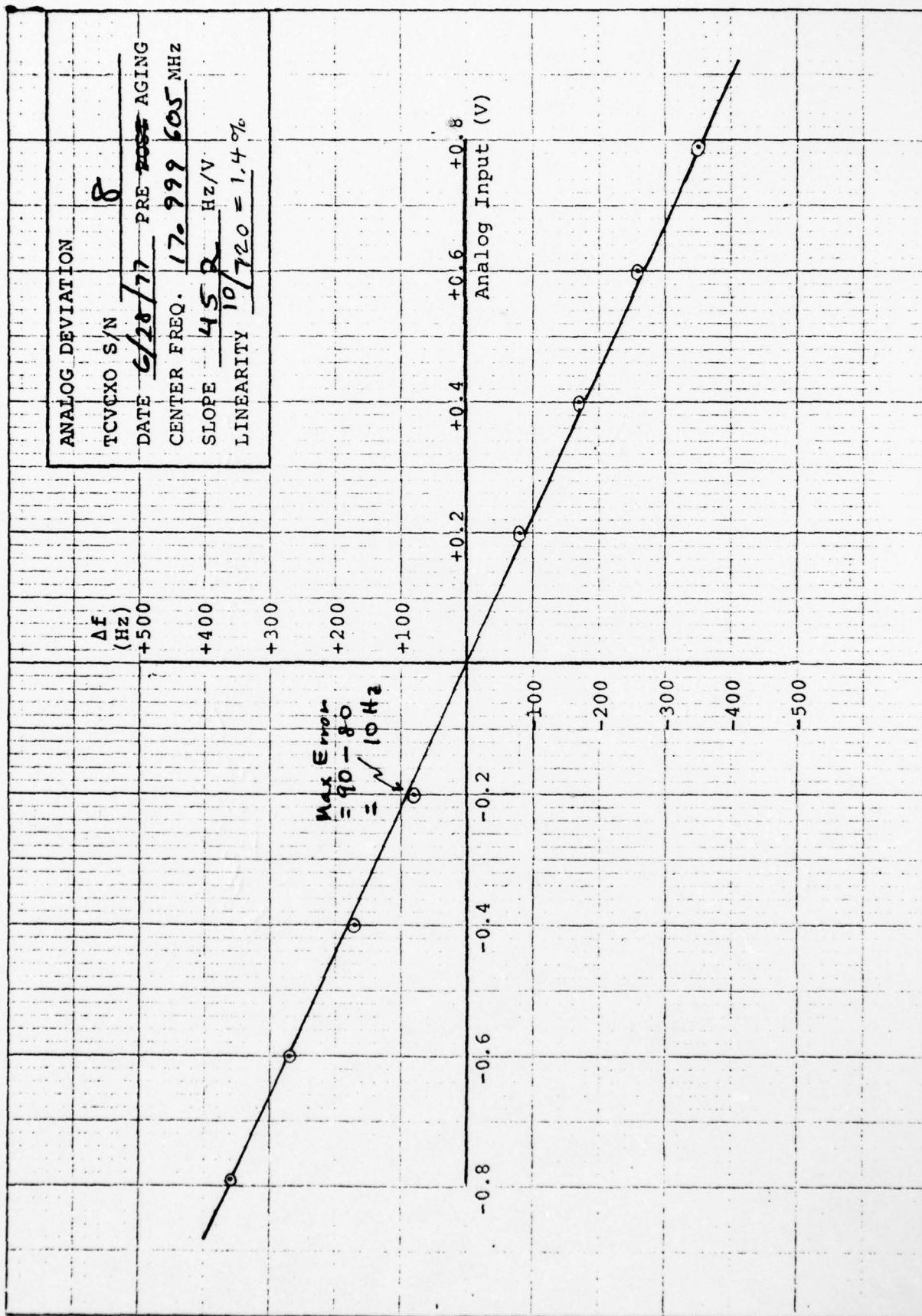
46 0 782

10 X 10 TO THE INCH 2 X 10 INCH 5
K10000 50000 TO 100000



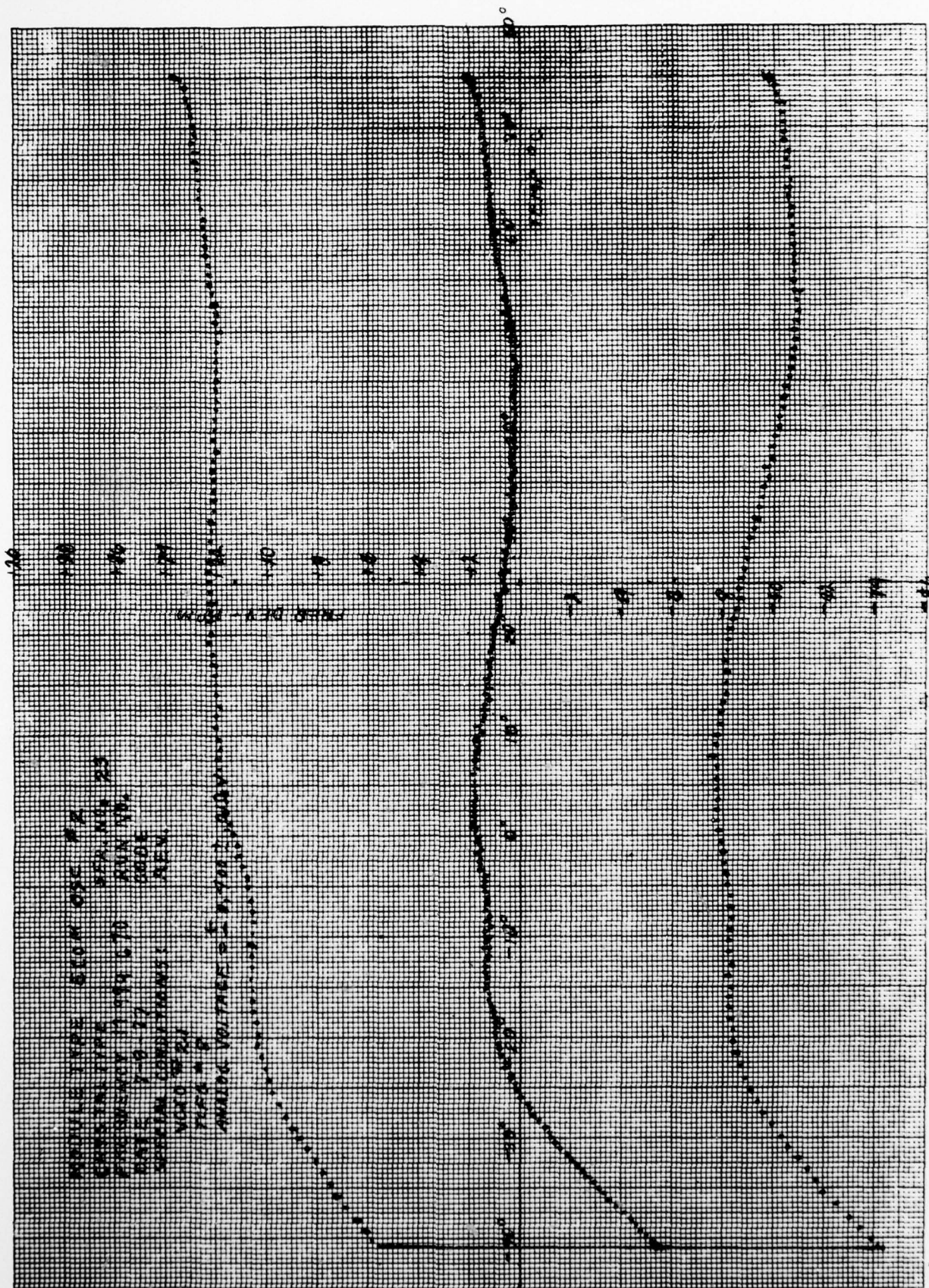






K-E 10 X 10 TO THE CENTIMETER 46 1517
 10 X 20 CM. ALJANEN
 MADE IN U.S.A.
 KESUPPEL & EGER CO.

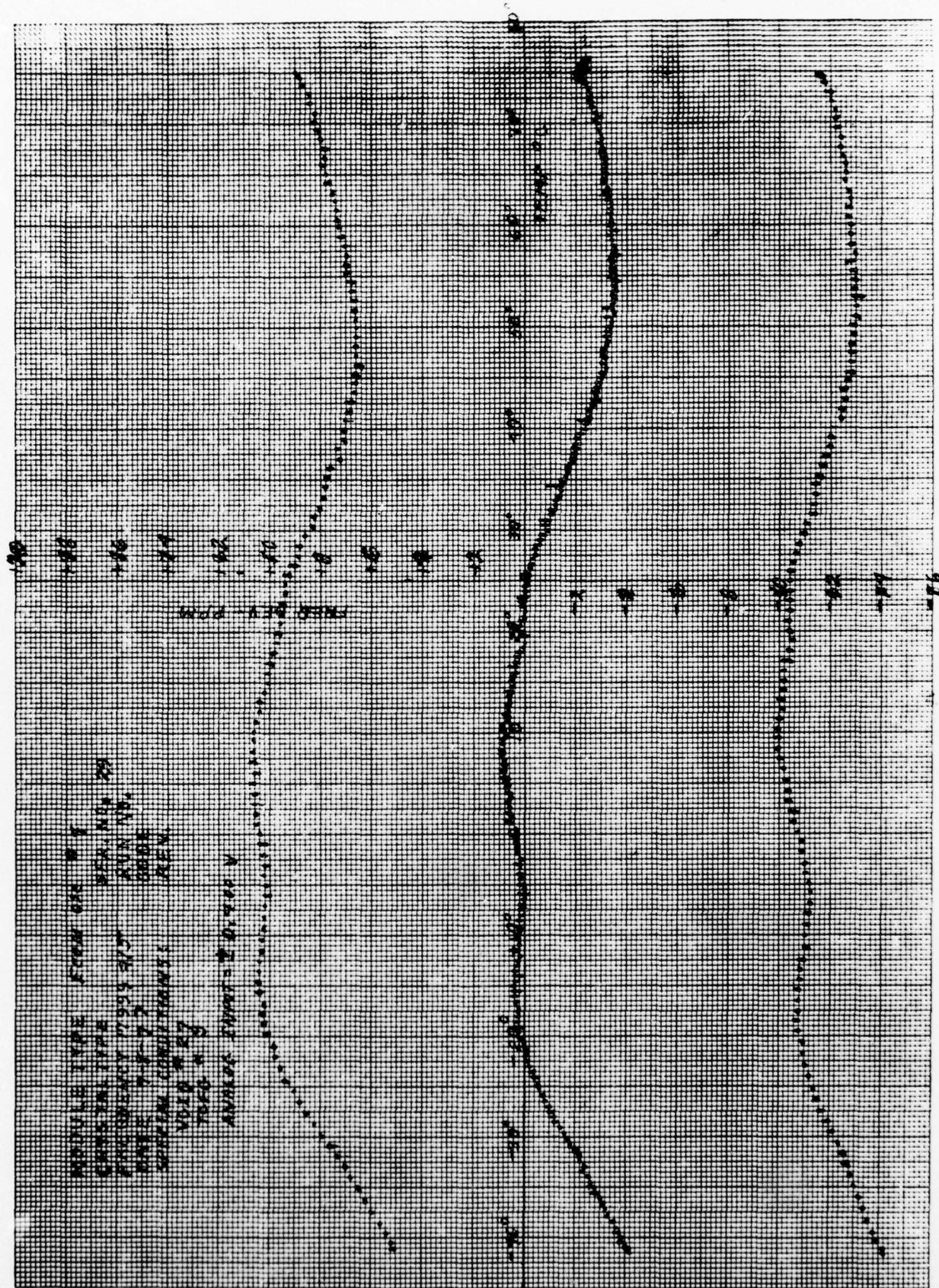
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 CRYSTAL TYPE 510M NO. 23
 FREQUENCY 1014.575 MHz
 RATE 1-0-17
 SERIAL CONDITIONS: NEW
 VOLTAGE 500V
 FREQ 100
 ANALOG VOLTAGE 5.000V



46 1517
MADE IN U. S. A.

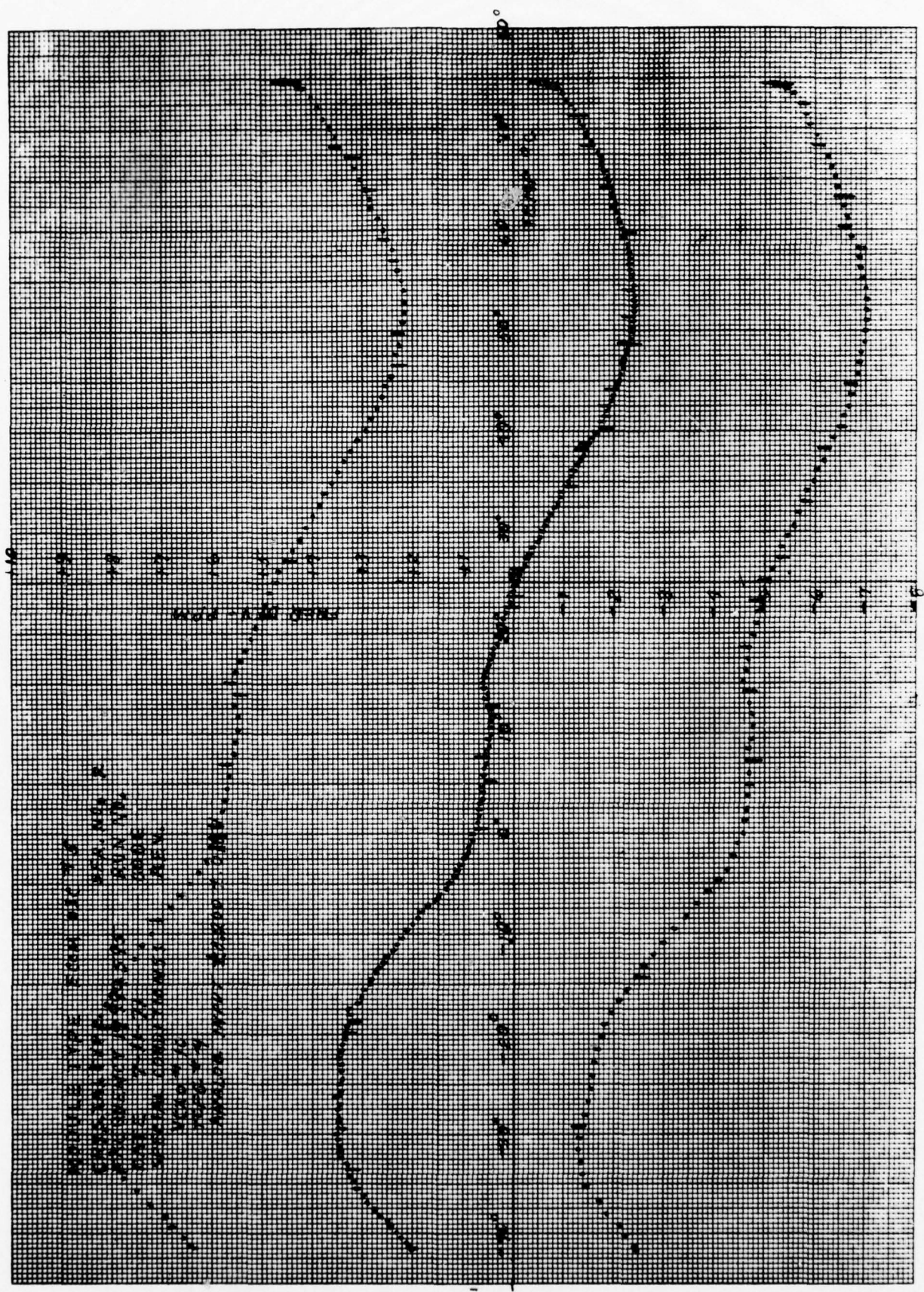


K-E 10 X 10 TO THE CENTIMETER 43 1517
 10 X 15 CM - ALBANYES
 KEUFFEL & ESSER CO.

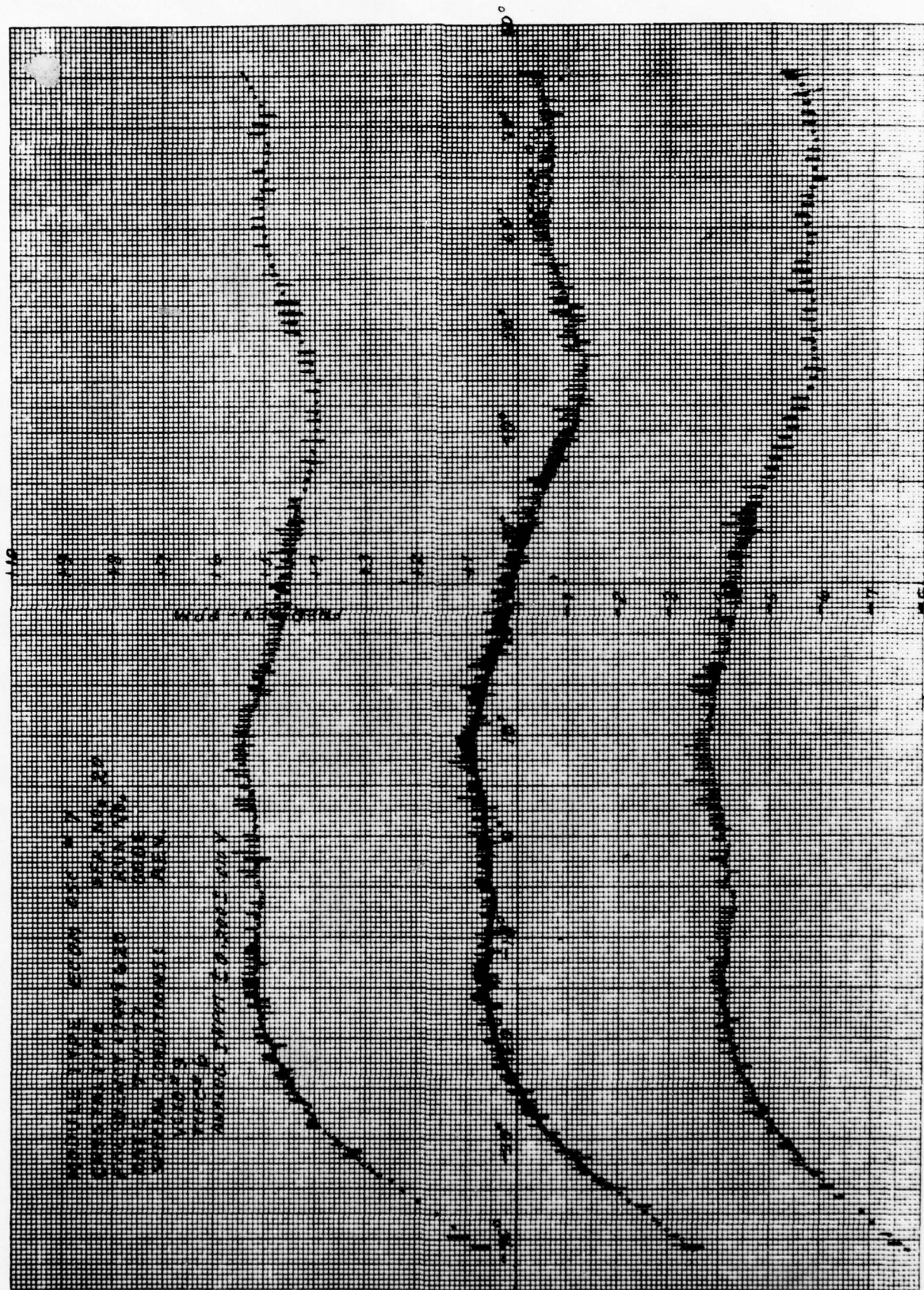


MODULE TYPE FROM 000 0 1
 CRYSTAL TYPE 000 000 20
 FREQUENCY 1000 000
 DATE 1-1-75
 SERIAL CONTINUED
 VOID # 27
 T000 0 1
 ANALOG INPUT 20.000 V

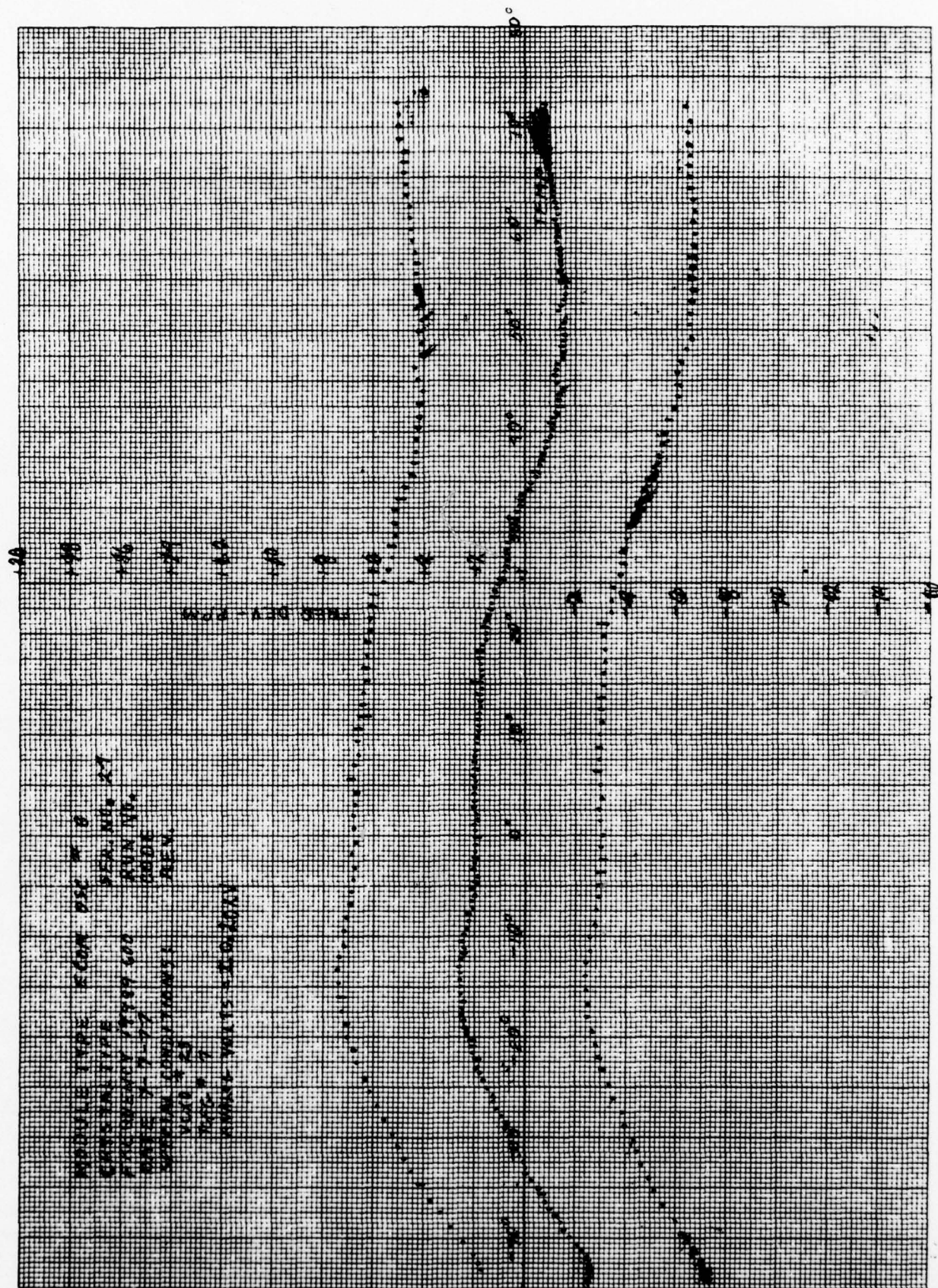
K-E 10 X 10 TO THE CENTIMETER 46 1517
 10 X 10 CM - ALBANES
 KEUFFEL & ESSER CO.



K-E 10 X 10 TO THE CENTIMETER 46 1517
 16 X 25 CM. ALGAMINE®
 KEUFFEL & ESSER CO.



K-E 10 X 10 TO THE CENTIMETER 46 1517
 10 X 25 CM - ALBANYES
 MADE IN U.S.A.
 KEUFFEL & ESSER CO.



APPENDIX I

TRS 31388

TCVCXO MODULE FUNCTIONAL TEST

RAYTHEON

RAYTHEON COMPANY
LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31388

SHEET
1 OF 9

REV -

TYPE OF SPEC

TEST REQUIREMENTS SPECIFICATION

TITLE OF SPEC

TCVCXO MODULE FUNCTIONAL TEST

FUNCTION	APPROVED	DATE	FUNCTION	APPROVED	DATE
WRITER	C. Morris	3-7-77			

REVISIONS

CHK	DESCRIPTION	REV	CHK	DESCRIPTION	REV

REVISION																				
SHEET NO.																				
REV STATUS OF SHEETS	REVISION	-	-	-	-	-	-	-	-											
	SHEET NO.	1	2	3	4	5	6	7	8											

1.0 SCOPE

This specification applies to the testing of the temperature-compensated, voltage controlled crystal oscillator (TCVCXO). It applies to the testing of the TCVCXO module assembly, the encapsulated TCVCXO module and the functional pairing of individual TCFG and VCXO hybrid microcircuits, prior to assembling these hybrids into a module. TCVCXO modules satisfying this specification will conform to the requirements of USAECOM Technical Requirements SCS-483, dated 17 January 1975, Sections 3 and 4, and Amendment 3, thereto, dated 14 June 1976, with the following exceptions. The transient frequency stability, frequency-temperature stability and aging requirements are covered by separate specifications.

2.0 APPLICABLE DOCUMENTS

SCS-483	Oscillator, Crystal, Temperature Compensated, Voltage Controlled (TCVCXO), 17 MHz to 22 MHz, Hermetic Seal
MIL-O-55310	Oscillators, Crystal, General Specification
31380	TCVCXO Module
31383	TCVCXO Electrical Schematic
31355	Substrate-Component Assembly, VCXO Hybrid
31357	Substrate-Component Assembly, TCFG Hybrid
31351-2,3	Final Assembly, VCXO Hybrid
31351-5	Final Assembly, TCFG Hybrid
31382	Electrical Test Flow Plan, TCVCXO Module

3.0 REQUIREMENTS

3.1 Test Equipment

<u>Equipment Item</u>	<u>Description</u>
1. Audio Oscillator	HP 200 CD or equivalent
2. Power supply	Harrison 855B or equivalent
3. Power supply	Harrison 855B or equivalent
4. Digital voltmeter	Fluke 8000A or equivalent
5. Oscilloscope	Tektronix 547 or equivalent
6. Frequency counter	HP 5360 or equivalent
7. Current probe and meter	HP 428 or equivalent
8. Patch Cords	

SIZE	CODE IDENT NO.	
A	49956	31388
SCALE	REV	SHEET 2 of 9

<u>Equipment Item</u>	<u>Description</u>
9. TCVCXO Functional Test Box	31366
10. TCVCXO Substrate-Component Assembly Functional Test Fixture	31373
11. Probe Card, Electrical Test	31372

3.2 Test Set-Up

The test equipment set-up shall be as shown in Figure 1. When testing individual TCFG and VCXO hybrids, paired together, the Functional Test Fixture is required; after assembly of the hybrids into a module, this fixture is not used in the set-up.

3.3 Functional Test

3.3.1 While performing this test fill in the TCVCXO Functional Tests Form (Figure 2).

3.3.2 Turn power off.

3.3.3 If testing a module, plug module into connector; if not, load hybrids and matching crystal (if required) into Functional Test Fixture.

3.3.4 Place power switch to 12V, Analog to 0V, FSK to Δ , Control to Analog, RF Load to 1000 ohms.

3.3.5 Turn power on.

3.3.6 Test No. 1, Input power.

3.3.6.1 Observe module current drain at the current loop. Record the value measured on the test form. The current must be less than 4.12 mA.

3.3.7 Test No. 2, RF Output.

3.3.7.1 Observe the RF Output at the RF test point with the oscilloscope. Record the peak to peak voltage. The value must be greater than 1.5 volt peak to peak.

3.3.8 Test No. 3, Frequency - Voltage stability.

SIZE	CODE IDENT NO.	
A	49956	31380
SCALE	REV	SHEET 3 of 9

RAYTHEONRAYTHEON COMPANY
LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31388

4 SHEET
OF 9

REV -

- 3.3.8.1 Observe the frequency of the TCVCXO.
After it has stabilized to within ± 0.5 HZ,
record the frequency in the 12 volt line,
- 3.3.8.2 Switch the power to + 10 VDC.
- 3.3.8.3 Record the frequency in the +10 volt line.
- 3.3.8.4 Switch the power to + 15 VDC.
- 3.3.8.5 Record the frequency in the + 15 volt line.
- 3.3.8.6 To be acceptable the frequency differences
between Steps 3.3.8.1 and 3.3.8.3 and
between 3.3.8.1 and 3.3.8.5 must be 0.25
PPM or less.
- 3.3.8.7 Restore the power switch to + 12 VDC.
- 3.3.9 Test No. 4 Frequency-Load Stability.
- 3.3.9.1 Observe the frequency of the TCVCXO.
After it has stabilized to within ± 0.5 HZ,
record the frequency on the 1000 ohms line.
- 3.3.9.2 Switch the RF load to 800 ohms.
- 3.3.9.3 Record the frequency on the 800 ohm line.
- 3.3.9.4 Switch the RF load to 1200 ohms.
- 3.3.9.5 Record the frequency on the 1200 ohm line.
- 3.3.9.6 Restore the RF load switch to 1000 ohms.
- 3.3.9.7 To be acceptable the frequency differences
between steps 3.3.9.1 and 3.3.9.3, and bet-
ween 3.3.9.1 and 3.3.9.5 must be 0.25 PPM or
less.
- 3.3.10 Test No. 5 Analog Input Impedance.
- 3.3.10.1 Switch the ANALOG control to the CAL position
and adjust the audio oscillator to 1KHz at
a level of 1.00 ± 0.01 VRMS as observed at
TP1. Record the actual value on the CAL
line.
- 3.3.10.2 Switch ANALOG to ZIN.

RAYTHEONRAYTHEON COMPANY
LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31388

SHEET
5 OF 9

REV

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- 3.3.10.3 Observe TP1 and record the RMS value on the ZIN line.
- 3.3.10.4 To be acceptable the value recorded on the Zin line must be greater than half the value recorded on the CAL line.
- 3.3.11 Test No. 6, Analog Frequency Deviation.
- 3.3.11.1 Put the ANALOG switch into the 0 volts position. After allowing the TCVCXO stabilize in frequency to within ± 0.5 HZ, adjust the frequency with Fadj to center frequency within ± 0.5 HZ. Record the output frequency.
- 3.3.11.2 Switch ANALOG to + 0.75 VDC.
- 3.3.11.3 Record frequency on output to ± 0.5 HZ.
- 3.3.11.4 Switch ANALOG to + 0.6 VDC.
- 3.3.11.5 Record frequency on output to ± 0.5 HZ.
- 3.3.11.6 Switch ANALOG + 0.4 VDC.
- 3.3.11.7 Record frequency on output to ± 0.5 HZ.
- 3.3.11.8 Switch ANALOG to + 0.2 VDC.
- 3.3.11.9 Record frequency on output to ± 0.5 HZ.
- 3.3.11.10 Switch ANALOG to - 0.2 VDC.
- 3.3.11.11 Record frequency on output to ± 0.5 HZ.
- 3.3.11.12 Switch ANALOG to - 0.4 VDC.
- 3.3.11.13 Record frequency on output to ± 0.5 HZ.
- 3.3.11.14 Switch ANALOG to - 0.6 VDC.
- 3.3.11.15 Record frequency on output to ± 0.5 HZ.
- 3.3.11.16 Switch ANALOG to - 0.75 VDC.
- 3.3.11.17 Record frequency on output ± 0.5 HZ.
- 3.3.11.18 Put ANALOG to OV.

RAYTHEONRAYTHEON COMPANY
LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31388

SHEET
OF 9

REV -

- 3.3.11.19 Verify the frequency observed on output agrees with the frequency recorded previously at OV to ± 1 HZ.
- 3.3.11.20 To determine if the performance data of this test is acceptable, do the following data reduction.
- 3.3.11.20.1 Taking the OV frequency as a reference, prepare a table of frequency deviations by subtracting the OV frequency from all readings.
- 3.3.11.20.2 Prepare a plot of frequency deviation vs. EANLG.
- 3.3.11.20.3 Determine the average slope of this plot this is the Analog Modulation Deviation Sensitivity and must be 500 HZ / volt ± 50 HZ / volt.
- 3.3.11.20.4 Draw a straight line, with the average slope through the plotted points in such a way that the plotted points fall equidistant from this line.
- 3.3.11.20.5 Deviation of the curve through the plotted points from the best straight line fit are defined as the linearity and shall not exceed ± 37.5 HZ.
- 3.3.12 Test No. 7 - FSK Deviation.
- 3.3.12.1 Verify that the TCVCXO is operating at center frequency to within ± 0.5 HZ as described in step 3.3.11.1 .
- 3.3.12.2 Place CONTROL to DIG.
- 3.3.12.3 Place FSK to $+\Delta$.
- 3.3.12.4 Observe the frequency and record the value to ± 0.5 HZ.
- 3.3.12.5 Place FSK to $-\Delta$.
- 3.3.12.6 Observe the frequency and record the value to ± 0.5 HZ.
- 3.3.12.7 To be acceptable the frequency differences between center frequency and the values recorded in Steps 3.3.12.4 and 3.3.12.6 must lie in the range of 300 to 325 HZ.

RAYTHEON

RAYTHEON COMPANY
LEXINGTON, MASS. 02173

CODE IDENT NO.

SPEC NO.

31388

49956

SHEET

7 OF 9

REV

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- 3.3.13 Shut down power.
- 3.3.14 Remove the TCVCXO module or hybrids from fixture as applicable.
- 3.3.15 Reject any module or hybrids not conforming to the test results specified herein.
- 4.0 NOTES - None.

RAYTHEONRAYTHEON COMPANY
LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31388

SHEET

8 OF 9

REV

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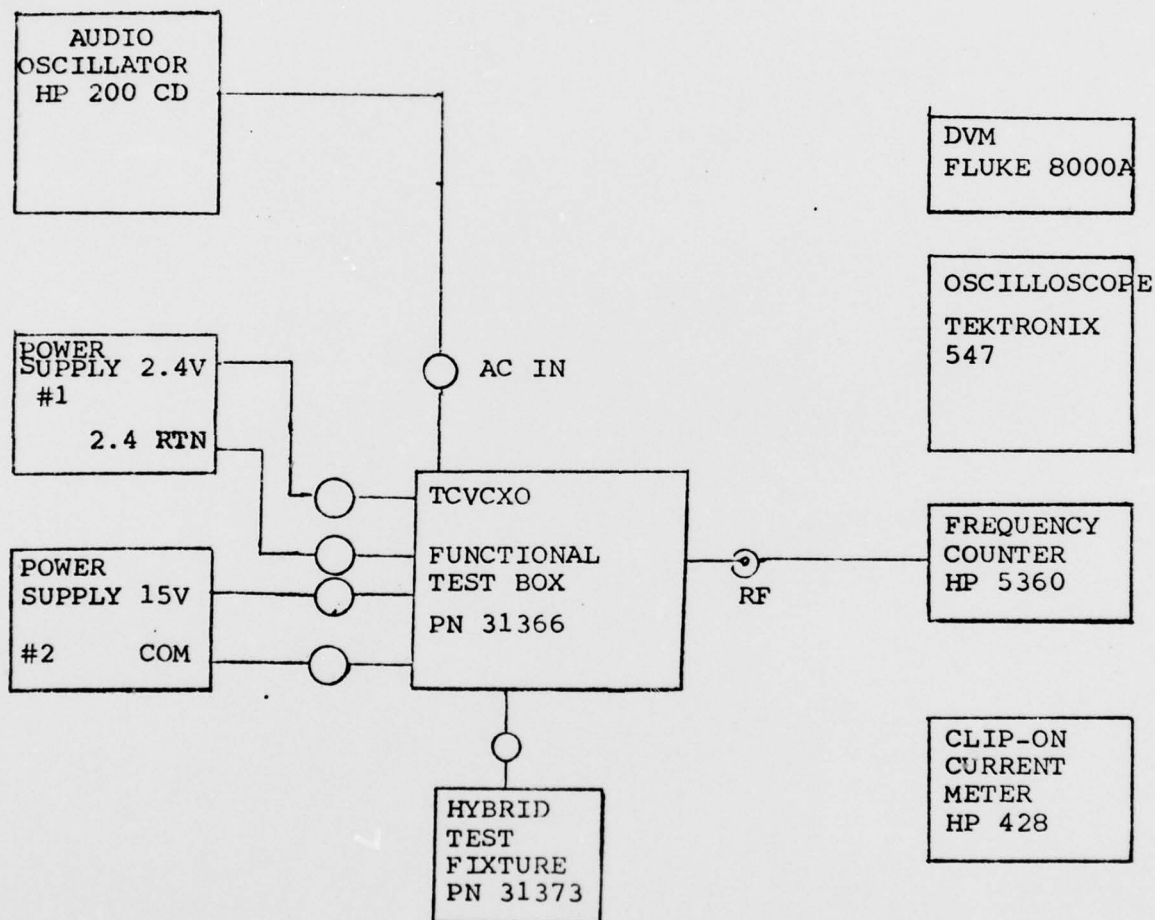
TCVCXO FINAL FUNCTIONAL TEST SETUP

FIGURE 1

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CODE IDENT NO.

49956

SPEC NO.

31388

SHEET

9 OF 9

REV -

TCVCXO FUNCTIONAL TESTS

TCVCXO MODULE NO. _____

TCFG NO. _____

VCXO NO. _____

XTAL NO. _____

FREQ. _____

DATE: _____

BY. _____

TEST NO.	INPUTS				CONDITION	SPEC.	TEST POINT	ACTUAL VALUE	COMMENT
	SUPPLY	EANL	EDIG	ECNT					
1. (Input P _z)	12	0	0	5	-	4.16 MA Max.	Cur. Lp.		
2. (RF OUT.)	12	0	0	5	R _L = 1000 Ω	1.5 VPP Max	Rf Tp		
3. (FR.-V.- Stab.)	10	0	0	5	R _L = 1000 Ω	0.25 PPM	Rf Tp		
	12					_____ Hz			
	15								
4. (Fr.-Ld.- Stab.)	12	0	0	5	800	0.25 PPM	Rf Tp		
					1000	_____ Hz			
					1200				
5. (Analog Z-in)	12	0	0	5	1.00VRMS 0.01, 1 kHz	200 K	TP1	Cal: Zin:	
6. (Analog Freq.- Dev. & Dev. Lin.)	12	0.75	0	5	At E _{ang} 0 v Adjust Fadj for Center Frequency After Stabiliza- tion	356.3 to 393.7	Rf		
		0.6							
		0.4							
		0.2							
		0.0							
		0.2							
		0.4							
		0.6							
		0.75				-393.7 to -356.3			
7. (Fsk. Dev.)	12	0	5	0	with Cntl in Anlg and Eanl OV, adjust Fadj for center freq	300 to 325	Rf		
			0		after Stab.	-325 to -300			

FIGURE 2

APPENDIX J

TRS 31389

TCVCXO MODULE TRANSIENT FREQUENCY STABILITY TEST

RAYTHEON**RAYTHEON COMPANY**
LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31389

2
OF 5

REV --

1.0 SCOPE

This specification applies to the testing of the temperature-compensated voltage-controlled crystal oscillator (TCVCXO) to demonstrate compliance with the Transient Frequency Stability requirement of USAECOM Technical Requirements SCS-483, dated 17 January 1975, Section 3.13, and amendment 3 thereto, dated 14 June 1976.

2.0 APPLICABLE DOCUMENTS

SCS-483	Oscillator, Crystal, Temperature-Compensated, Voltage-Controlled (TCVCXO), 17 MHz to 22 MHz, Hermetic Seal.
MIL-O-55310	Oscillators, Crystal, General Specification for
31380	TCVCXO Module
31383	TCVCXO Electrical Schematic
31382	Electrical Test Flow Plan, TCVCXO

3.0 REQUIREMENTS**3.1** TEST EQUIPMENT

<u>Equipment Item</u>	<u>Description</u>
1. Power Supply	Harrison 855B or equivalent
2. Oscilloscope	Tektronix 547
3. Frequency Counter	HP 5360
4. Keyboard Programmer	HP 5375
5. Function Generator	Exact 301 or equivalent
6. Pulse Generator	Interstate Instruments PG-2 or equivalent
7. TCVCXO Functional Test Box	31366
8. Patch cords, as required	

3.2 TEST SET-UP

The test equipment set-up will be as shown in figure 1.

3.3 TURN ON TEST

- 3.3.1 Test data shall be recorded on the Transient Frequency Stability form shown in figure 2.
- 3.3.2 Turn power off.
- 3.3.3 Plug the TCVCXO module into the connector on the TCVCXO Functional Test Box, and place the thermal shield in place.
- 3.3.4 Switch ANALOG to OV, Control to DIG, FSK to - Δ , and Turn On to Norm,

RAYTHEONRAYTHEON COMPANY
LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31389

SHEET
2 OF 5

REV ---

- 3.3.5 Place the 5360 counter in the MODULE mode.
- 3.3.6 Turn on power.
- 3.3.7 Observe the frequency and verify that it is stable to within ± 0.5 Hz.
Record this value as F initial.
- 3.3.8 Switch TURN-ON to the TEST position.
- 3.3.9 Set the 5375 programmer to the START position and set the 5360 counter to the EXTERNAL mode.
- 3.3.10 Depress the push button on the EXACT 301.
- 3.3.11 The 5375 programmer should be in the PAUSE mode. RECALL the contents of storage registers a, b, and c and record the frequency displayed respectively.
- 3.3.12 Set the 5360 counter to the MODULE mode.
- 3.3.13 Observe the frequency and record it as F final.
- 3.3.14 Turn power off.
- 3.3.15 To determine if the results of this test are acceptable, do the following data reduction on the test form.
- 3.3.15.1 Subtract F initial from each frequency recorded and enter the result; in the "change in frequency" column.
- 3.3.15.2 The change in frequency entered in the F initial row must be less than 1 Hz.
- 3.3.15.3 The change in frequency entered in the F100 row must be less than 9 Hz.

4.0 NOTES
None

RAYTHEONRAYTHEON COMPANY
LEXINGTON, MASS. 02173

CODE IDENTIFIER

49956

SPEC NO.

31389

SHEET
4 OF 5

REV --

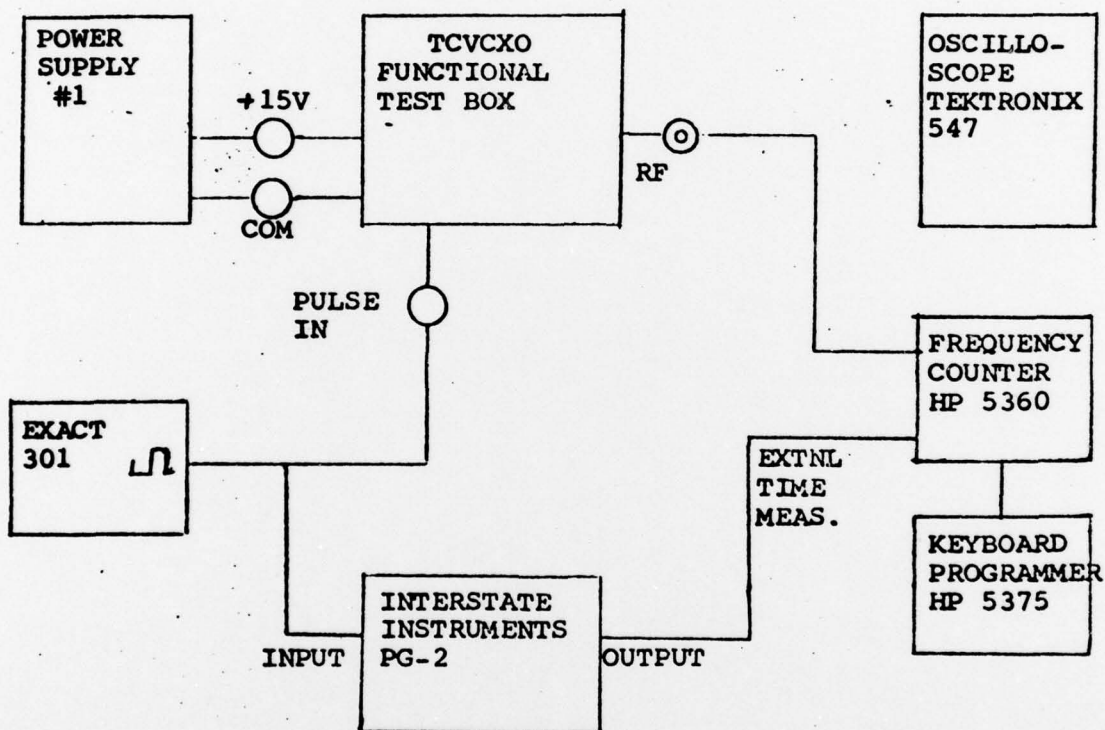
TCVCXO TURN-ON TEST SETUP

FIGURE 1

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LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31389

SHEET

5 OF 5

REV

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TCVCXO
TRANSIENT FREQUENCY STABILITY

TCVCXO MODULE NO: _____

TCFG NO: _____

VCXO NO: _____

DATE: _____

XTAL NO: _____

BY: _____

TEST NO.	FREQUENCY	CHANGE IN FREQ.
1.	F_{initial}	0
2.	F_5	
	F_{50}	
	F_{100}	
3.	F_{final}	

FIGURE 2

APPENDIX K

TRS 31390

TCVCXO MODULE TEMPERATURE TEST

RAYTHEONRAYTHEON COMPANY
LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31390

SHEET

1 OF 8

REV

TYPE OF SPEC

TEST REQUIREMENTS SPECIFICATION

TITLE OF SPEC

TCVCXO MODULE TEMPERATURE TEST

FUNCTION	APPROVED	DATE	FUNCTION	APPROVED	DATE
WRITER					

REVISIONS

CHK	DESCRIPTION	REV	CHK	DESCRIPTION	REV

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REVISION	-	-	-	-	-	-	-	-											
SHEET NO.	1	2	3	4	5	6	7	8											
REV STATUS OF SHEETS	REVISION																		
	SHEET NO.																		

RAYTHEONRAYTHEON COMPANY
LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31390

2 SHEET
OF 8

REV -

1.0 SCOPE

This specification applies to the testing of the temperature-compensated voltage-controlled crystal oscillator (TCVCXO) to demonstrate compliance with the temperature requirement of USAECOM Technical Requirements SCS-483, dated 17 January 1975, Section 3.10 and admendment 3 thereto, dated 14 June 1976.

2.0 APPLICABLE DOCUMENTS

SCS-483 Oscillator, Crystal, Temperature-Compensated, Voltage-Controlled (TCVCXO), 17 MHz to 22 MHz, hermetic seal.

MIL-O-55310 Oscillators, Crystal, General Specification for

31380 TCVCXO Module

31383 TCVCXO Electrical Schematic

31382 Electrical Test Flow Plan, TCVCXO

3.0 REQUIREMENTS3.1 Test EquipmentEquipmentDescription

- | | |
|--|--------------------------------|
| 1. Power Supply | Harrison 855 B or equivalent |
| 2. Power Supply | Harrison 855 B or equivalent |
| 3. Power Supply | Harrison 855 B or equivalent |
| 4. Function Generator | Exact 301 or equivalent |
| 5. Clip On Ammeter | HP-428 or equivalent |
| 6. Digital Voltmeter | Fluke 8000 or equivalent |
| 7. Digital Voltmeter | Fluke 8000 or equivalent |
| 8. Frequency Counter | HP 5248L or equivalent |
| 9. XY Plotter | Mosely 7000 AM or equivalent |
| 10. Oscilloscope | Tektronix 547 or equivalent |
| 11. D/A Converter | HP 580A or equivalent |
| 12. RCL Bridge | Cal.Std. WB 110B or equivalent |
| 13. Oven | Delta MK 2300 or equivalent |
| 14. Remote Oven Control (Raytheon built) | |
| 15. Electronic Switch | 31393 |

RAYTHEONRAYTHEON COMPANY
LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31390

SHEET
3 OF 8

REV -

3.2 Test Set-Up

The test set up to be used is shown in Figure 1. Perform test with ECNTL = 5V, EDIG = 0V. To carry out this specification the TCVCXO module is to be installed in a special fixture attached to the inside cover of the Delta oven, designed to filter out the sharp thermal transients induced by normal oven cycling. The oven will be made to scan the temperature range -45°C to $+75^{\circ}\text{C}$ under program control while an XY plot is being made of center frequency and both positive and negative analog deviations. The attached TCVCXO Temperature Tests form (Figure 2) is to be filled out at the start of the test as well as during a run.

3.3 Procedure**3.3.1** Turn off power.**3.3.2** Place TCVCXO module into oven test fixture.**3.3.3** Turn power on.**3.3.4** Set EANLG to 0 VDC ECNTL to 5 VDC, and E DIG to 0 VDC.

3.3.5 Observe the frequency and allowing sufficient time for the reading to stabilize to ± 1.0 Hz, adjust the internal F ADJ for a frequency of F - 50 Hz, and record the value in the fo (Ti) blank. For this step do not insert the oven door assembly into the oven.

3.3.6 Record as TINITIAL the temperature of the TCVCXO module as read from the RCL resistor.

3.3.7 Derive the DEVIATION in hertz and enter the result on the form.

3.3.8 Set E ANLG to a positive voltage from power supply No. 1 and adjust power supply No. 1 until the frequency shifts positive from fo (Ti), step 3.3.5, by the amount of the deviation. Record the value power supply No. 1 is set to in the VD blank.

3.3.9 Switch E ANLG to 0V, E CNTL to 0V, Record the frequency in F - V_D blank.

3.3.10 Switch E DIG to 5 VDC. Record the frequency in the F + V_D blank.

3.3.11 Record the data of steps 3.3.9-10 in the appropriate columns of the DIGITAL DEVIATION form.

3.3.12 Switch E DIG to 0V, ECNTL to + 5 VDC.

3.3.13 Close the oven door and lower the chamber temperature to -45°C . Allow sufficient stabilization time for the frequency to remain within ± 1 Hz.

3.3.14 Record the temperature of the TCVCXO module as read from the RCL resistor in the second row of the DIGITAL DEVIATION form (Figure 3).

RAYTHEONRAYTHEON COMPANY
LEXINGTON, MASS. 02173

49956

31390

SHEET
OF 8 REV -

- 3.3.15 Record the frequency in the f_0 column.
- 3.3.16 Switch E CNTL to OV and record the frequency in the $F - V_D$ blank.
- 3.3.17 Switch E DIG to +5V and record the frequency in the $F + V_D$ blank.
- 3.3.18 Switch E DIG to OV, E CNTL to +5V.
- 3.3.19 Start the temperature run program and engage the electronic switch into the driven mode.
- 3.3.20 Throughout the ensuing temperature run, it will be necessary to monitor the XY plotting to ensure that no problems develop that would reduce the value of the data being generated. Specifically the ink flow must remain controlled.
- 3.3.21 Commencing of -40°C and repeating every 5°C interval thereafter, the following data is to be recorded on the test form.
- 3.3.21.1 Observe value of the RCL and record in RCL column.
- 3.3.21.2 Observe TPl and record value.
- 3.3.21.3 Observe 9V and record value.
- 3.3.21.4 Observe +12V current and record value.
- 3.3.21.5 Observe RF wave on scope and record peak to peak value.
- 3.3.22 When the temperature run reaches 75°C , RAISE THE PEN.
- 3.3.23 Disengage the Electronic Switch and set E ANLG to OV. Record the frequency in the f_0 column of the DD form.
- 3.3.24 Switch E ANLG to OV, E CNTL to OV. Record the frequency in $F - V_D$ blank.
- 3.3.25 Switch E DIG to 5 VDC. Record the frequency in the $F + V_D$ blank.
- 3.3.26 Record the data of steps 3.3.24-25 in the appropriate columns of the DIGITAL DEVIATION form.
- 3.3.27 Switch E DIG to OV, E CNTL to + 5VDC.
- 3.3.28 Put the oven in the manual mode and set the oven to 25°C .
- 3.3.29 Allow sufficient time to stabilize the frequency to within $\pm 1^\circ\text{C}$ and record the oven temperature T FINAL and the oscillator frequency f_0 (T_5). Shut down power.
- 3.3.30 Remove TCVCXO module. Evaluate test data according to the following data reduction.

RAYTHEONRAYTHEON COMPANY
LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31300

SHEET

5 OF 8

REV -

- 3.3.31 Take the XY plot and measure the difference, on the center frequency curve, between the most positive deviation and the most negative deviation and convert this value in Hz to PPM. The number so derived must be less than 5 PPM.
- 3.3.32 Take the XY plot and measure the difference, on the positive shift curve, between the most positive deviation and the most negative deviation, and convert this value in Hz to PPM. The number so derived must be less than 4 PPM.
- 3.3.33 Take the XY plot and measure the difference on the negative shift curve, between the most positive deviation and the most negative deviation and convert this value in Hz to PPM. The number so derived must be less than 4 PPM.

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LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

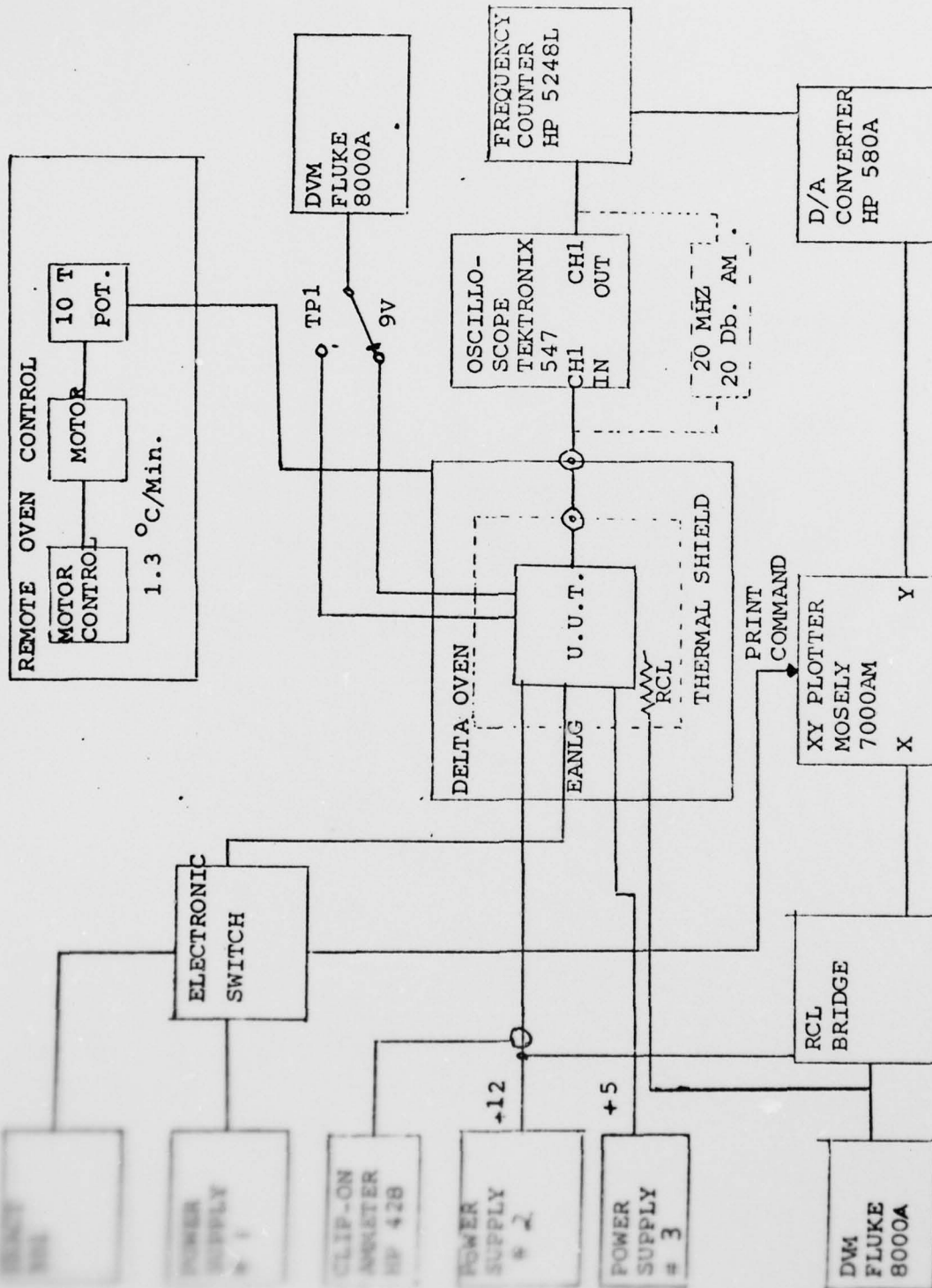
SPEC NO.

31390

SHEET

6 OF 8

REV



TCVCXO TEMPERATURE TEST SET UP

FIGURE 1

RAYTHEONRAYTHEON COMPANY
LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31390

SHEET

7 OF 8

REV

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TCVCXO TEMPERATURE TESTS

TCVCXO MODULE NO: _____

FREQ(F) _____ Mhz.

TCFG NO: _____

XTAL NO. _____

VCXO NO: _____

 $T_i = T_{\text{initial}} =$ _____ $^{\circ}\text{C}$ $f_o(T_i) =$ _____ Hz. $T_f = T_{\text{final}} =$ _____ $^{\circ}\text{C}$ $f_o(T_f) =$ _____ Hz.BY _____ + V_D _____ Volts 5F _____ HzDATE _____ DEVIATION = ± 325 Hz.

TEMP($^{\circ}\text{C}$)	RCL(Ω)	9 Volt	TP1(v)	IDC(MA)	RFOUT(PP)	COMMENT
-40						
-35						
-30						
-25						
-20						
-15						
-10						
-5						
0						
5						
10						
15						
20						
25						
30						
35						
40						
45						
50						
55						
60						
65						
70						
75						

FIGURE 2

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LEXINGTON, MASS. 02173

CODE IDENT NO.

49956

SPEC NO.

31390

SHEET
8 OF 8

REV -

TCVCXO TEMPERATURE TEST - DIGITAL DEVIATION

TCVCXO MODULE NO: _____

FREQ. (F) _____ Mhz.

TCFG NO: _____

XTAL NO: _____

VCXO NO: _____

BY: _____

DATE: _____

TEMP (°C)	RCL (Ω)	f ₀ (HZ)	f _{+Vd} (HZ)	f _{-Vd} (Hz)	+ Δ	- Δ

FIGURE 3